Fundamental thermal noise limits for optical microcavities

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We present a joint theoretical and experimental characterization of thermo-refractive noise in high quality factor (Q), small mode volume (V) optical microcavities. Analogous to well-studied stability limits imposed by Brownian motion in macroscopic Fabry-Perot resonators, microcavity thermo-refractive noise gives rise to a mode volume-dependent maximum effective quality factor. State-of-the-art fabricated microcavities are found to be within one order of magnitude of this bound. We confirm the assumptions of our theory by measuring the noise spectrum of high-Q/V silicon photonic crystal cavities and apply our results to estimate the optimal performance of proposed room temperature, all-optical qubits using cavity-enhanced bulk material nonlinearities.

Introduction.— Room temperature, high-quality factor (Q) optical cavities enable the investigation of new physical phenomena by enhancing light-matter interaction [1], shaping electromagnetic modes [2], and modifying the vacuum photon density of states [3]. However, these advantages come with an often forgotten cost — interaction with a thermally equilibrated confining medium inherently injects noise into the optical mode in accordance with the fluctuation-dissipation theorem (FDT) [4]. Macroscopic resonators (Fig. 1a), such as those implemented in gravitational wave interferometers, minimize this interaction by supporting a large mode volume $\tilde{V} \gg 1$ in vacuum, where $\tilde{V} = V/(\lambda/n)^3$ for the volume V of a λ -wavelength optical mode confined in a refractive index n. The surprising realization that the sensitivity of these \sim km-long cavities can still be limited by Brownian motion in few μ m-thick mirror coatings [5, 6] has spurred interest in low-noise mirror coatings [7], grating-based mirrors [8, 9], and the fundamental limits of macroscopic cavities in the presence of thermal fluctuations [10–12].

Here, we consider the opposite case: optical microcavities (Fig. 1b) [13], whose small mode volumes ($\tilde{V} \sim 1$) facilitate low-energy (even single-photon level) nonlinear interactions [14], single molecule label-free sensing [15], and enhanced coupling for atom-photon interfaces [16, 17]. However, compared to macroscopic cavities, the fundamental temperature fluctuations $\langle \delta T^2 \rangle \propto 1/V$ [18, 19] are much larger in these near-diffraction-limited modes. The associated refractive index fluctuations, so called "thermo-refractive noise" (TRN), become a principal source of resonant frequency noise in dielectric microcavities including microspheres [20], whispering-gallery mode resonators [21], ring resonators [22], and photonic crystal (PhC) cavities [23]. TRN has also recently been shown to limit the stability of dielectric nanolasers [24] and microcavity frequency combs [25].

To date, microcavity TRN has only been considered in a pertubative regime, where the resulting rms resonant frequency fluctuation $\delta\omega_{\rm rms} \simeq 1/\sqrt{V}$ is much less than the loaded cavity linewidth $2\Gamma = \omega_0/Q$. For sufficiently high Q and small V, this assumption becomes

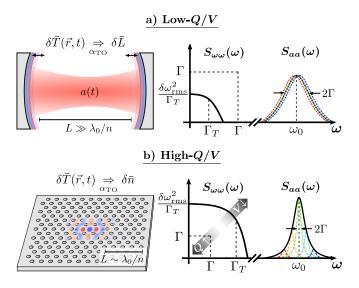


FIG. 1. Comparison of thermo-refractive noise (TRN) in macroscopic resonators and microcavities. Mode-averaged temperature fluctuations δT in large cavities induce refractive index noise $\delta \bar{n}$ (and thus pathlength changes $\delta \bar{L}$) due to the mirrors' non-zero thermo-optic coefficient $\alpha_{TO} = dn/dT$. The large mode volume V reduces $\delta \overline{T}$, yielding a narrowband resonant frequency noise spectrum $S_{\omega\omega}(\omega)$ and an rms resonant frequency fluctuation $\delta \omega_{\rm rms} \ll \Gamma$, the cavity half-linewidth. This non-dominant thermal noise inhomogeneously broadens the intracavity field spectrum $S_{aa}(\omega)$. Decreasing V increases both the magnitude $\delta \omega_{\rm rms}$ and bandwidth Γ_T of TRN, while increasing the resonator quality factor $Q = \omega_0/2\Gamma$ causes both quantities to exceed Γ . TRN therefore becomes a dominant source of homogeneous broadening in wavelength-scale high-Q/V microcavities, leading to thermal dephasing and reduced resonant excitation efficiency of the cavity field a(t).

invalid. Continued improvements in microcavity performance — yielding $Q > 10^7$, $\tilde{V} \sim 1$ through fabrication advances [26] and $Q \sim 10^5$, $\tilde{V} \sim 10^{-3}$ using novel subwavelength dielectric features [27] — thus raises a simple question: when will fundamental thermal noise limit the performance of high-Q/V microcavities?

In this Article, we answer this open question by deriving general bounds for optical microcavity performance in the presence of TRN and find that current devices are within one order of magnitude of this bound. We verify our theory by measuring TRN as the dominant noise source in high-Q/V PhC cavities and demonstrate the ability to distinguish between sub-wavelength mode volumes ($\tilde{V} < 1$) using fundamental noise spectra. As an example of the immediate impact of our formalism, we analyze the implications for an outstanding goal in quantum photonics: all-optical qubits using cavity-enhanced bulk material nonlinearities [28]. Our results highlight the importance of considering thermal noise in state-ofthe-art optical resonators and also inform design choices to minimize its impact on device performance.

Formalism.— As schematically illustrated in Fig. 1, fundamental stochastic temperature fluctuations $\delta T(\vec{r}, t)$ within a cavity confining medium of refractive index nand thermo-optic coefficient $\alpha_{\rm TO} = dn/dT$ drive a modeaveraged refractive index change $\delta \bar{n}(t) = \alpha_{\rm TO} \delta \bar{T}(t)$. For an optical mode completely confined in dielectric, the resulting resonance shift $\delta \omega(t) = \omega_0 \alpha_{\rm TO} \delta \bar{T}(t)/n$ follows from first-order perturbation theory [29]. We neglect temperature-induced deformations of the cavity, as the thermo-elastic coefficient of typical dielectrics is two orders of magnitude smaller than $\alpha_{\rm TO}$ [21].

In the presence of TRN, the steady-state rotatingframe intra-cavity field amplitude is

$$\tilde{a}(t) = i\sqrt{\Gamma}\tilde{s}_{\rm in} \int_{-\infty}^{t} \mathrm{d}t' e^{-(i\Delta+\Gamma)(t-t')-i\int_{t'}^{t} \mathrm{d}t''\delta\omega(t'')} \quad (1)$$

for a loaded amplitude decay rate Γ and critically-coupled static drive \tilde{s}_{in} detuned by Δ from the cavity resonance. The associated statistical moments can be computed using the moment-generating properties of the characteristic functional $\langle e^{i\int_{t'}^{t}\delta\omega_0(t'')dt''}\rangle$, which in the case of zeromean Gaussian noise only requires the autocorrelation $\langle\delta\omega(t)\delta\omega(t+\tau)\rangle = (\omega_0\alpha_{\rm TO}/n)^2 \langle\delta\bar{T}(t)\delta\bar{T}(t+\tau)\rangle$ [30, 31]. The latter autocorrelation of temperature fluctuations can be computed from the heat equation

$$\frac{\partial}{\partial t}\delta T(\vec{r},t) + D_T \nabla^2 \delta T(\vec{r},t) = F_T(\vec{r},t)$$
(2)

in a medium of thermal diffusivity D_T driven by a Langevin forcing term $F_T(\vec{r}, t)$ which satisfies the FDT. As we will illustrate for slab PhC cavities, Eqn. 2 can be solved analytically for specific geometries; however, for generality we follow the approach of Ref. [32] and enforce a single-mode decay approximation by introducing a phenomenological thermal decay rate

$$\Gamma_T = D_T \frac{\int \left[\nabla \left(\epsilon(\vec{r}) |\vec{E}(\vec{r})|^2\right)\right]^2 \mathrm{d}^3 \vec{r}}{\int \epsilon(\vec{r})^2 |\vec{E}(\vec{r})|^4 \mathrm{d}^3 \vec{r}}$$
(3)

evaluated for the envelope of intracavity energy density. This form of Γ_T is chosen for consistency with $\langle \delta \bar{T}^2 \rangle = k_B T_0^2 / c_V V_T$, the well-known statistical mechanics result for temperature fluctuations in a volume V_T of specific heat capacity c_V in thermal equilibrium with a bath temperature T_0 [33]. Averaging Eqn. 2 over the optical mode profile, we then find

$$\frac{\mathrm{d}}{\mathrm{d}t}\delta\bar{T}(t) + \Gamma_T\delta\bar{T}(t) = \bar{F}_T(t), \qquad (4)$$

leading to the solution

$$\langle \delta\omega(t)\delta\omega(t+\tau)\rangle = \underbrace{\left(\frac{\omega_0}{n}\alpha_{\rm TO}\right)^2 \frac{k_B T_0^2}{c_V V_T}}_{\delta\omega_{\rm rms}^2} e^{-\Gamma_T |\tau|},\qquad(5)$$

where the thermal mode volume

$$V_T = \frac{\left[\int \epsilon(\vec{r}) |\vec{E}(\vec{r})|^2 d^3 \vec{r}\right]^2}{\int \epsilon(\vec{r})^2 |\vec{E}(\vec{r})|^4 d^3 \vec{r}}$$
(6)

is the common Kerr nonlinear mode volume found by solving Eqn. 2 in a homogeneous medium [20]. For a three-dimensional mode with a Gaussian energy density distribution, V_T is larger than the standard Purcell mode volume $V = \int \epsilon |\vec{E}|^2 d^3 \vec{r} / \max\{\epsilon |\vec{E}|^2\}$ by a factor of $2\sqrt{2}$.

Combining Eqns. 1 and 5, we can solve for the statistical moments of $\tilde{a}(t)$ as a function of the primary parameters V_T and Γ_T . Complete derivations are provided in Supplementary Section I. If $V_T(Q)$ is sufficiently large (small) such that $\Gamma \gg (\delta \omega_{\rm rms}, \Gamma_T)$ as in previous analyses, TRN can be treated perturbatively (Fig. 1a). In this case, the cavity resonance is quasistatic over the photon decay period and shifts by much less than a cavity linewidth over time: TRN thus contributes to weak inhomogeneous broadening of the resonance. However, as the thermal mode volume V_T shrinks, $\delta \omega_{\rm rms}$ and Γ_T increase until they eventually exceed Γ (Fig. 1b). The spectral density of the intracavity field is then homogeneously broadened to a linewidth $2\Gamma + 2\delta\omega_{\rm rms}^2/\Gamma_T \approx 2\delta\omega_{\rm rms}^2/\Gamma_T$ by TRN. Our analysis focuses on the transition to this high-Q/V limit. Specifically, we solve Eqn. 1 with nonperturbative TRN to calculate mode volume-dependent maximum "effective" cavity quality factors $Q_{\rm eff}$ to describe energy storage and dephasing in microcavities.

Measurement.— Before pursuing these goals, we first experimentally verify the fundamental assumptions of our TRN model by measuring the noise spectrum of high-Q/V PhC cavities. As shown in Fig. 2, our setup uses a Mach-Zehnder interferometer to measure the phase of a cavity reflection signal via balanced homodyne detection. A variable beamsplitter separates the emission from an amplified tunable infrared laser into local oscillator (LO) and cavity input paths, which are passively balanced to minimize laser frequency noise coupling. A $\lambda/2$ -plate rotates the input signal polarization by 45° relative to the dominant cavity polarization such that the cavity reflection can be isolated from any specular reflection from the sample using a polarizing beamsplitter (PBS) [34]. The sample stage is temperature controlled to better than

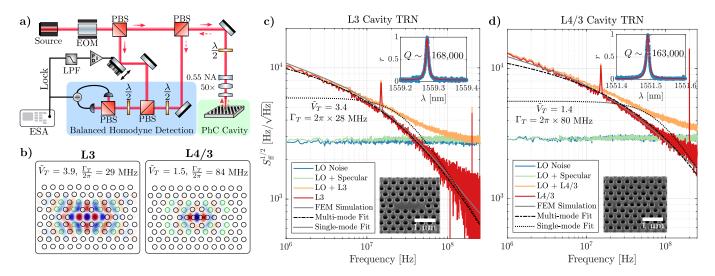


FIG. 2. Calibrated measurement of thermo-refractive noise (TRN) in high-Q/V silicon PhC cavities. A shot noise-limited, balanced homodyne detector (a) is locked to the phase quadrature of the cavity reflection signal and records the spectrum of resonant frequency fluctuations. The simulated mode profiles, thermal mode volume \tilde{V}_T (Eqn. 6), and thermal decay rate Γ_T (Eqn. 3) of the L3 and L4/3 devices tested are shown in (b). The radii of the green holes are increased by up to 5% to form superimposed gratings which improve vertical coupling efficiency. The measured spectral density of cavity resonant frequency noise $S_{\rm ff}(f)$ (red) for L3 (c) and L4/3 (d) cavities is compared to noise from a specular reflection off the sample surface, finite-element method (FEM) simulations of cavity TRN, as well as single- and multi-mode fits. The listed multi-mode fit parameters agree with the predicted values in (b). Inset reflection spectra of each device reveal quality factors on the order of 10⁵. Micrographs of the fabricated designs with enlarged holes relative to the optimal designs in (b) are also inset.

10 mK using a Peltier plate and feedback temperature controller. A balanced, shot noise-limited photodetector measures the homodyne signal from the recombined cavity reflection and LO, and the result is recorded on an electronic spectrum analyzer (ESA). By actively locking to the phase quadrature of the homodyne signal with a piezo-controlled mirror, TRN-induced cavity frequency noise is detected as frequency-resolved voltage noise. To calibrate the spectrum, we inject a known phase noise with an electro-optic modulator (EOM) whose modulation efficiency is measured by sideband fitting [35].

Fig. 2 shows the resulting measurements for two released (air-clad) silicon PhC cavities: the common L3 cavity and the recently-proposed "L4/3" cavity [36, 37]. Fabricated cavities yield high quality factors (up to $Q \approx$ 400,000 at $\lambda_0 \approx 1550$ nm) with efficient vertical coupling. The variation of Purcell mode volume — $\tilde{V} =$ (0.95, 0.32) for simulated L3 and L4/3 cavities, respectively — also allows us to confirm the expected volumedependence of TRN. Whereas a direct reflection from the sample surface (green trace) adds little additional noise to the LO background (blue), we observe broadband, input power-independent noise from either cavity's reflection (orange). The calibration tone is visible at 200 MHz and we attribute the resonance at ~ 15 MHz to optomechanical coupling from the fundamental flexural mode of the suspended membrane [38]. In the corrected cavity noise curve (red), we have subtracted the LO shot noise and accounted for attenuation due to the finite cavity linewidth. As expected, the wavelength-scale mode

volumes yield a spectral density of resonant frequency fluctuations $S_{\rm ff}(f)$ with nearly two orders of magnitude larger amplitude and bandwidth compared to previous results in microspheres [20] and ring resonators [22]. Supplementary Section II further details the experiments and provides TRN data as a function of cavity input power.

The measured noise spectra show excellent agreement with numerical simulations based on a modified version of the fluctuation-dissipation theorem for thermo-refractive noise [39]. A noise model based on a multi-mode solution to Eqn. 2 in a thin slab is also well-fitted to the data, yielding the fit parameters $\{\tilde{V}_T^{L3}, \Gamma_T^{L3}/2\pi, \tilde{V}_T^{L4/3}, \Gamma_T^{L4/3}/2\pi\} = \{3.4 \pm 0.3, 28 \pm$ 1 MHz, 1.4 ± 0.1 , 80 ± 3 MHz that compare favorably with the expected values ({3.9, 29 MHz, 1.5, 84 MHz}) from Eqn. 6 (evaluated numerically from the simulated mode profiles) and Eqn. 3. In Eqn. 3, we assume a twodimensional Gaussian mode and reduced thermal diffusivity $D_T = D(1-\phi)/(1+\phi)$ for the patterned slab with porosity ϕ compared to the unpatterned thin film diffusivity D [40, 41]. As predicted, the reduced mode volume of the L4/3 cavity increases the bandwidth and spectral density of thermal fluctuations.

The noise spectra of the proposed single-mode approximation (Eqn. 5) underestimates the measured noise of both devices at low frequencies $\omega \ll \Gamma_T$, but accurately approximate $S_{\rm ff}$ in the range of frequencies of interest (near and above the cutoff frequency Γ_T) and conserve the integrated frequency noise $\langle \delta \omega_{\rm rms}^2 \rangle$. These results indicate that TRN is the dominant broadband noise source in high-Q/V resonators, and validate the suitability of a single-mode approximation to describe the spectrum of frequency fluctuations in general microcavity geometries. More broadly, our demonstration unveils a new technique for evaluating the mode volume of fabricated optical resonators using fundamental quantities as opposed to complex invasive techniques, such as near-field scanning optical microscopy [27].

Q/V Limits. — Given this experimental confirmation, we can apply our TRN model to estimate the fundamental performance limits of room temperature microcavities. We specifically consider the quality factor to mode volume ratio Q/V, which is proportional to the peak intracavity intensity and therefore of particular significance for single-photon nonlinearities [42] and enhanced sensitivity to point-like defects [43].

The effective quality factor $Q_{\text{eff}} = \omega_0 \langle |\tilde{a}(t)|^2 \rangle / 2|\tilde{s}_{\text{in}}|^2$ of interest in this case is the ratio of intracavity energy $\langle |\tilde{a}(t)|^2 \rangle$ to energy input per cycle $2|\tilde{s}_{\text{in}}|^2/\omega_0$ in a resonantly excited, critically-coupled cavity. Under the same conditions, solving Eqn. 1 for $\langle |\tilde{a}(t)|^2 \rangle$ subject to the noise autocorrelation of Eqn. 5 yields

$$\frac{Q_{\text{eff}}}{\tilde{V}} = \frac{\omega_0}{2\Gamma_T \tilde{V}} e^x x^{-s} \gamma_l(s, x) \tag{7}$$

where γ_l is the lower incomplete Gamma function, $x = (\delta \omega_{\rm rms}/\Gamma_T)^2$, and $s = \Gamma/\Gamma_T + x$. Intuitively, decreasing the cavity linewidth 2Γ well below the broadened linewidth $2\delta \omega_{\rm rms}^2/\Gamma_T$ has little impact: the prolonged energy storage offsets the reduced excitation rate of the rapidly shifting resonance, leaving the intracavity energy unaltered. $Q_{\rm eff}$ is maximized in this limiting case. The corresponding upper bound of Eqn. 7 at T = 300 K is plotted for various material systems in Fig. 3 as a function of \tilde{V} assuming a three-dimensional Gaussian mode in a homogeneous three- or two-dimensional confining medium. In the latter case, the decay rate $\Gamma_T = 3\pi D_T/V^{2/3}$ decreases by a factor of $3\sqrt{2}V^{1/3}$ to account for the restricted dimensionality of thermal diffusion.

In the joint limit $(\delta\omega_{\text{RMS}}, \Gamma) \ll \Gamma_T$, valid for sufficiently high-Q, low V cavities, Eqn. 7 simplifies to $Q_{\text{eff}}^{\text{max}} = \omega_0 \Gamma_T / 2\delta\omega_{\text{rms}}^2$, thereby recovering the broadened linewidth $2\delta\omega_{\text{rms}}^2/\Gamma_T$. $Q_{\text{eff}}^{\text{max}}$ then scales as $V^{1/3}$ in a homogeneous medium, indicating that larger mode volumes reduce the integrated thermo-optic noise, as expected. For this reason, recent ultra-high- $Q (Q > 10^8)$ integrated resonators have been specifically designed with $\tilde{V} \gg 1$ to limit TRN [52, 53]. Alternatively, Fig. 3 illustrates the advantage of reducing V to maximize $Q_{\text{eff}}^{\text{max}}/V$. Further optimization of sub-wavelength cavities [27, 54] could therefore improve the intensity enhancement achievable in room temperature devices.

While our review of high-Q/V cavities (Fig. 3) in various materials shows that all fabricated cavities obey the projected bounds, silicon PhC slab cavities [26] and silica microtoroids [45] lie within an order of magnitude of

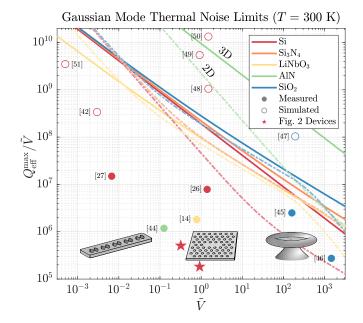


FIG. 3. Thermal noise-limited room temperature quality factor to mode volume ratios $(Q_{\rm eff}^{\rm eff}/\tilde{V})$ for the materials considered in Supplementary Section III assuming a Gaussianshaped mode at $\lambda_0 = 1550$ nm admitting thermal diffusion in two or three dimensions (dash-dot and solid lines, respectively). These limits are compared our devices as well as other fabricated and proposed microcavities. Insets illustrate typical confinement geometries for the range of \tilde{V} listed.

the thermal noise limit. Furthermore, various simulated devices [47–50] exceed the limit; their practical realization will thus require low-temperature operation or novel noise suppression techniques.

Implications for All-Optical Qubits. — These proposed thermal noise limits have practical impact for future devices. Chief among the applications driving the pursuit for high-Q/V cavities is quantum information. Recent photonic proposals [55, 56] have explored the feasibility of reaching the qubit limit of cavity nonlinear optics [28] at room temperature by leveraging the relative immunity of optical photons to thermal noise. While this insensitivity is granted by Planck's Law, we have shown here that through the thermo-refractive effect, temperature fluctuations can significantly impact light in a high-Q/V resonator. For coherent processes, TRN-induced dephasing of the field amplitude $\tilde{a}(t)$ must be considered in addition to the previously discussed intracavity energy limitations. We therefore define the effective quality factor $Q_{\text{eff}} = \omega_0 |\langle \tilde{a}(t) \rangle|^2 / 2 |\tilde{s}_{\text{in}}|^2$ based on the mean field amplitude of a resonant, critically-coupled cavity, yielding

$$Q_{\rm eff} = \frac{\omega_0}{2\Gamma_{\rm eff}} = Q \left(\frac{\Gamma}{\Gamma_T}\right)^2 e^{2x} x^{-2s} \gamma_l^2(s, x) \qquad (8)$$

for the previously defined x, s.

We can compare Γ_{eff} to a nonlinear coupling rate g between qubit basis states with the simple figure of merit FOM = g/Γ_{eff} , which intuitively corresponds to the num-

Photonic Qubit Figures of Merit (Silicon Cavity, T = 300 K)

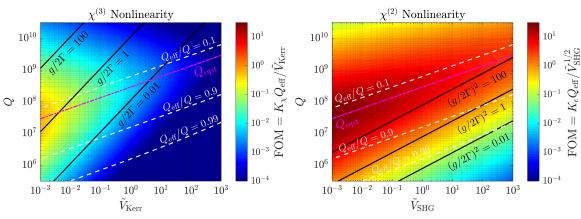


FIG. 4. Performance of room temperature all-optical qubits using bulk $\chi^{(3)}$ (left) or electric field-induced $\chi^{(2)}$ (right) nonlinearities in silicon microcavities as a function of loaded cavity quality factor Q at $\lambda_0 = 2.3 \,\mu\text{m}$ and the relevant normalized nonlinear mode volume \tilde{V} ($\tilde{V}_{\text{Kerr}} = \tilde{V}_T$ and \tilde{V}_{SHG} , assumed to be equal to \tilde{V}_T , for $\chi^{(3)}$ and $\chi^{(2)}$, respectively). The figure of merit (FOM) — the ratio of qubit coupling rate g to the composite decay and thermal dephasing rate $2\Gamma_{\text{eff}} = \omega_0/Q_{\text{eff}}$ is largest for strong coupling $(g/2\Gamma, (g/\Gamma)^2 \gg 1)$ and weak dephasing ($Q_{\text{eff}} \approx Q$). Three dimensional thermal diffusion in a homogenous medium is assumed.

ber of qubit operations that can be completed prior to decay or dephasing. For bulk $\chi^{(3)}$ and $\chi^{(2)}$ nonlinearities, the coupling rate g is a function of material parameters and mode volumes. For $\chi^{(3)}$, $g = 2\Gamma K_{\chi}/\tilde{V}_{\text{Kerr}} \gg 2\Gamma$ is required to reach the strong coupling regime where the anharmonicity of Fock state energies decouples the qubit basis (zero and one photon states) from higher energy states [28]. Similarly, $g = 2\Gamma K_{\epsilon}/\tilde{V}_{\text{shg}}^{1/2}$ is the coupling rate between doubly resonant first- and second-harmonic basis states using the bulk $\chi^{(2)}$ nonlinearity, which requires $(g/2\Gamma)^2 \gg 1$ for strong coupling. Derivations of the proportionality constants K_{χ} , K_{ϵ} and mode volumes are included in the Supplementary Section IV. The resulting figures of merit

$$\text{FOM}_{\chi^{(3)}} = K_{\chi} \frac{Q_{\text{eff}}}{\tilde{V}_{\text{Kerr}}} \qquad \text{FOM}_{\chi^{(2)}} = K_{\epsilon} \frac{Q_{\text{eff}}}{\tilde{V}_{\text{SHG}}^{1/2}} \qquad (9)$$

are plotted in Fig. 4 for Gaussian modes in silicon, where we assume the intrinsic $\chi^{(3)}$ nonlinearity can create an electric-field induced $\chi^{(2)} = 3\chi^{(3)}E_{\rm dc}$ near the breakdown dc electric field $E_{\rm dc}$ [57].

An ideal qubit operates well within the strong coupling regime with minimal dephasing. In the presence of TRN, increasing Q/V improves the former at the cost of the latter, leading to the observed mode volume-dependent optimum loaded quality factor $Q_{\rm opt} \approx \omega_0 \Gamma_T / 2\delta \omega_{\rm rms}^2$. Fig. 4 also illustrates a relative performance advantage for $\chi^{(2)}$ devices in silicon, as strong coupling can be achieved at lower quality factors. For example, the peak FOM_{$\chi^{(2)}$} ~ 10 is three orders of magnitude greater than FOM_{$\chi^{(3)}$} assuming $Q = Q_{\rm opt}$ and $\tilde{V}_{\rm Kerr} = \tilde{V}_{\rm SHG} = 1$. Although small $\tilde{V}_{\rm SHG}$ — which involves maximizing a nonlinear overlap function between two co-localized cavity modes — is generally more difficult to achieve than

small \tilde{V}_{Kerr} [58], FOM_{$\chi^{(2)}$} $\propto \tilde{V}_{\text{SHG}}^{-1/2}$ also demonstrates favorable scaling at larger mode volumes.

Conclusion.— This brief example manifests the practical limitations imposed by fundamental thermal noise in microcavities while highlighting design choices that optimize device performance in its presence. Both outcomes rely on proper noise characterization. Towards this end, we have presented a general theory for thermo-refractive noise in optical microcavities and experimentally verified our model by measuring the effect of temperature fluctuations in high-Q/V silicon PhC cavities. The results show that non-perturbative TRN ultimately limits the achievable quality factor in small mode volume cavities and that experimental devices have neared this fundamental bound. Violating the observed tradeoff between mode volume and thermo-optic noise stands as an exciting avenue for future investigation that we are currently pursuing. Ultimately, these improvements will be necessary to achieve the performance required for further advances in optical quantum information processing, cavity optomechanics, precision optical sensing, and beyond.

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Supplemental Materials: Fundamental thermal noise limits for optical microcavities

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I. THERMO-REFRACTIVE NOISE (TRN) THEORY

While the development of ultrahigh-performance optical resonators has only recently warranted its study within optical systems, stochastic temperature fluctuations are a fundamental concept in thermodynamics [S1]. Assuming Boltzmann statistics within a finite volume V with specific heat capacity c_V at temperature T, we find

$$\langle \delta T^2 \rangle = \frac{k_B T^2}{c_V V}.\tag{S1}$$

2. Balanced Homodyne Detector

15

Chanacterization

In optical microcavities, V approaches diffraction limited volumes leading to temperature fluctuations that significantly impact the resonance stability in materials with a temperature-dependent refractive index.

Here, we derive the associated thermo-refractive noise (TRN) spectrum in an optical microcavity under the singlemode approximation described in the main text. Using this approximation, the intracavity field statistics are derived. In the typical perturbative limit where the rms frequency fluctuation is much smaller than the loaded cavity linewidth $(\delta \omega_{\rm rms} \ll 2\Gamma_l)$, we use perturbation theory to solve for the evolution of the cavity field a(t) and the associated noise spectrum $S_{aa}(t)$. We also provide general solutions for the first and second statistical moments of a(t), which are used in the main text to derive "effective" quality factors in the presence of thermal noise. The solution for $S_{aa}(t)$ in the limiting case of high-Q cavities — where the thermal decay rate $\Gamma_T \gg \Gamma_l$ and the frequency noise can be assumed to be white — is also provided. Finally, we compare the single-mode noise spectrum to that derived from a formal solution to heat diffusion in an infinite two dimensional slab, which we found to most accurately model the specific geometry of the photonic crystal microcavities in our experiments.

A few notes on convention: 1) we derive two-sided angular frequency noise spectra $S_{\omega\omega}(\omega)$, but plot one-sided frequency spectra $S_{\rm ff}(f) = 2S_{\omega\omega}(2\pi f)/2\pi = S_{\omega\omega}(2\pi f)/\pi$ for experimental measurements to conform with the common conventions of the gravitational wave community; 2) temporal coupled mode theory decay rates Γ_i are amplitude decay rates; the associated quality factors are therefore defined as $Q_i = \omega_0/2\Gamma_i$.

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A. Statistics of Microcavity TRN

To first order, the change in resonant frequency under a permittivity perturbation $\delta\epsilon(\vec{r},t)$ can be expressed as

$$\frac{\delta\omega(t)}{\omega_0} = -\frac{1}{2} \frac{\int_{\delta\epsilon} \delta\epsilon(\vec{r},t) |\vec{E}(\vec{r})|^2 \mathrm{d}^3 \vec{r}}{\int \epsilon |\vec{E}(\vec{r})|^2 \mathrm{d}^3 \vec{r}} \approx -\frac{\int_{\delta n} n \, \delta n(\vec{r},t) |\vec{E}(\vec{r})|^2 \mathrm{d}^3 \vec{r}}{\int \epsilon |\vec{E}(\vec{r})|^2 \mathrm{d}^3 \vec{r}} = -\frac{1}{V_{\mathrm{eff}}} \frac{\int_{\delta n} n \, \delta n(\vec{r},t) |\vec{E}(\vec{r})|^2 \mathrm{d}^3 \vec{r}}{\max\{\epsilon |\vec{E}(\vec{r})|^2\}} \tag{S2}$$

where we have made the approximation $\delta \epsilon \approx 2n\delta n$ and introduced the standard mode volume

$$V_{\rm eff} = \frac{\int \epsilon(\vec{r}) |\vec{E}(\vec{r})|^2 {\rm d}^3 \vec{r}}{\max\{\epsilon |\vec{E}(\vec{r})|^2\}}.$$
(S3)

The change in refractive index $\delta n(\vec{r}, t)$ is directly proportional to temperature change $\delta T(\vec{r}, t)$, with the thermo-optic coefficient $\alpha_{TO} = dn/dT$ serving as the constant of proportionality. We therefore find

$$\frac{\delta\omega(t)}{\omega_0} = -\frac{1}{V_{\text{eff}}} \frac{\int_{\delta n} \alpha_{\text{TO}} \delta T(\vec{r}, t) n |\vec{E}(\vec{r})|^2 \mathrm{d}^3 \vec{r}}{\max\{\epsilon |\vec{E}(\vec{r})|^2\}}.$$
(S4)

Alternatively, Eqn. S2 can be evaluated for a uniform, mode averaged temperature change $\delta \bar{T}(t)$ assuming complete confinement of the mode within a homogeneous medium. This approach yields

$$\frac{\delta\omega(t)}{\omega_0} = -\frac{1}{n}\alpha_{\rm TO}\delta\bar{T}(t).$$
(S5)

Comparing Eqns. S4 and S5, we find

$$\delta \bar{T}(t) = \frac{1}{V_{\text{eff}}} \frac{\int \delta T(\vec{r}, t) \epsilon(\vec{r}) |\vec{E}(\vec{r})|^2 \mathrm{d}^3 \vec{r}}{\max\{\epsilon |\vec{E}(\vec{r})|^2\}}.$$
(S6)

Eqn. S5 can now be solved using the mode averaged temperature change, whose evolution is derived from the heat equation (given a thermal diffusivity D_T)

$$\frac{\partial \delta T(\vec{r},t)}{\partial t} - D_T \nabla^2 \delta T = F_T(\vec{r},t) \tag{S7}$$

driven by a thermal Langevin source $F_T(\vec{r}, t)$ with the statistics [S2]

$$\langle F_T(\vec{r}_1, t_1) F_T^*(\vec{r}_2, t_2) \rangle = \frac{2D_T k_B T_0^2}{c_V} \delta(t_1 - t_2) \vec{\nabla}_{\vec{r}_1} \cdot \vec{\nabla}_{\vec{r}_2} [\delta(\vec{r}_1 - \vec{r}_2)]$$
(S8)

that satisfy the fluctuation-dissipation theorem. Averaging over the mode, we find the approximation

$$\frac{\mathrm{d}(\delta\bar{T}(t))}{\mathrm{d}t} + \Gamma_T \delta\bar{T}(t) = \bar{F}_T(t),\tag{S9}$$

where Γ_T is introduced as a phenomenological thermal decay rate whose form will be chosen later to ensure the form of $\langle \delta \bar{T}^2 \rangle$ matches the canonical result from statistical mechanics (Eqn. S1). In analog with $\delta \bar{T}(t)$, the mode averaged thermal force $\bar{F}_T(t)$ is

$$\bar{F}_T(t) = \frac{1}{V_{\text{eff}}} \frac{\int F_T(\vec{r}, t) \epsilon(\vec{r}) |\vec{E}(\vec{r})|^2 \mathrm{d}^3 \vec{r}}{\max\{\epsilon |\vec{E}(\vec{r})|^2\}}.$$
(S10)

The steady-state solution of Eqn. S9,

$$\delta \bar{T}(t) = \int_{-\infty}^{t} \bar{F}(t') e^{-\Gamma_T(t-t')} \mathrm{d}t', \qquad (S11)$$

can then be used to find the corresponding statistics of the temperature fluctuation at equilibrium (i.e. $\log t$):

$$\langle \delta \bar{T}(t) \delta \bar{T}(t+\tau) \rangle = \int_{-\infty}^{t} \mathrm{d}t' \int_{-\infty}^{t+\tau} \mathrm{d}t'' \langle \bar{F}_{T}(t') \bar{F}_{T}(t'') \rangle e^{-\Gamma_{T}(t-t')} e^{-\Gamma_{T}(t+\tau-t'')}.$$
 (S12)

The result requires the autocorrelation of $\bar{F}_T(t)$, which is readily evaluated using the mode averaged form of Eqn. S10:

$$\langle \bar{F}_{T}(t)\bar{F}_{T}^{*}(t+\tau)\rangle = \underbrace{\frac{2D_{T}k_{B}T_{0}^{2}}{c_{V}V_{\text{eff}}^{2}} \frac{\int \mathrm{d}^{3}\vec{r} \left[\vec{\nabla} \left(\epsilon(\vec{r})|\vec{E}(\vec{r})|^{2}\right)\right]^{2}}{(\max\{\epsilon|\vec{E}(\vec{r})|^{2}\})^{2}}}_{\mathcal{R}_{\bar{F}_{T}\bar{F}_{T}}(0)}\delta(\tau) = \mathcal{R}_{\bar{F}_{T}\bar{F}_{T}}(0)\delta(\tau).$$
(S13)

Inserting this result into Eqn. S12 along with the change of variables $t'' \rightarrow t' + \tau'$ yields

$$\langle \delta \bar{T}(t) \delta \bar{T}(t+\tau) \rangle \approx \int_{-\infty}^{t} \mathrm{d}t' \int_{-t'}^{t+|\tau|-t'} \mathrm{d}\tau' \langle \bar{F}_{T}(t') \bar{F}_{T}^{*}(t'+\tau') \rangle e^{-2\Gamma_{T}(t-t')} e^{-\Gamma_{T}(|\tau|-\tau')}$$

$$\approx \int_{-\infty}^{t} \mathrm{d}t' e^{-2\Gamma_{T}(t-t')} \int_{-t'}^{t+|\tau|-t'} \mathrm{d}\tau' \mathcal{R}_{\bar{F}_{T}\bar{F}_{T}}(0) \delta(\tau') e^{-\Gamma_{T}(|\tau|-\tau')}$$

$$\langle \delta \bar{T}(t) \delta \bar{T}(t+\tau) \rangle \approx \frac{\mathcal{R}_{\bar{F}_{T}\bar{F}_{T}}(0)}{2\Gamma_{T}} e^{-\Gamma_{T}|\tau|}.$$
(S14)

Correspondence with Eqn. S1 therefore requires

$$\frac{\mathcal{R}_{\bar{F}_T\bar{F}_T}(0)}{2\Gamma_T} = \frac{k_B T_0^2}{c_V V} \Rightarrow \mathcal{R}_{\bar{F}_T\bar{F}_T}(0) = \frac{2k_B T_0^2 \Gamma_T}{c_V V}.$$
(S15)

The same correspondence for a general frequency-domain solution to Eqn. S7 in an infinite homogeneous medium (where the phenomenological parameter Γ_T is not introduced; see Section IB) mandates [S3]

$$V = V_T = \frac{V_{\text{eff}}^2}{V_{\text{eff}}^{(2)}} = \left[\frac{\int \epsilon |\vec{E}(\vec{r})|^2 \mathrm{d}^3 \vec{r}}{\max\{\epsilon |\vec{E}(\vec{r})|^2\}}\right]^2 / \underbrace{\frac{\int \epsilon^2 |\vec{E}(\vec{r})|^4 \mathrm{d}^3 \vec{r}}{\max\{\epsilon^2 |\vec{E}(\vec{r})|^4\}}}_{V_{\text{eff}}^{(2)}}$$
(S16)

Comparing Eqn. S15 to Eqn. S13 then lends a calculable form of the decay rate Γ_T :

$$\Gamma_T = D_T \frac{\int \mathrm{d}^3 \vec{r} \left[\vec{\nabla} \left(\epsilon(\vec{r}) |\vec{E}(\vec{r})|^2\right)\right]^2}{\int \mathrm{d}^3 \vec{r} \epsilon(\vec{r})^2 |\vec{E}(\vec{r})|^4}.$$
(S17)

The autocorrelation of the cavity resonance frequency is directly proportional to this result given $\delta \bar{\omega}_0(t) \approx -(\omega_0/n)\alpha_{\rm TO}\delta \bar{T}(t)$ (as dictated by first-order perturbation theory):

$$\left| \left\langle \delta\omega(t)\delta\omega(t+\tau) \right\rangle \approx \left(\frac{\omega_0}{n}\alpha_{\rm TO}\right)^2 \frac{\mathcal{R}_{\bar{F}_T\bar{F}_T}(0)}{2\Gamma_T} e^{-\Gamma_T|\tau|} = \left(\frac{\omega_0}{n}\alpha_{\rm TO}\right)^2 \frac{k_B T_0^2}{c_V V_T} e^{-\Gamma_T|\tau|} = \delta\omega_{\rm rms}^2 e^{-\Gamma_T|\tau|}.$$
(S18)

B. Derivation of the Thermal Mode Volume

For completeness, we recapitulate the derivation of the thermal mode volume V_T (introduced in Section IA) in an infinite homogeneous medium [S4], where Fourier modes can be used to solve solve Eqn. S7:

$$\frac{\partial \delta T(\vec{r},t)}{\partial t} - D_T \nabla^2 \delta T = F_T(\vec{r},t) \Rightarrow \delta T(\omega,\vec{k}) = \frac{F(\omega,\vec{k})}{i\omega + D_T |\vec{k}|^2}.$$
(S19)

Taking the temperature mode average in Eqn. S6 and inverse Fourier transforming yields

$$\delta \bar{T}(t) = \frac{1}{(2\pi)^4 V_{\text{eff}}} \int d^3 \vec{r} \frac{\epsilon |\vec{E}(\vec{r})|^2}{\max\{\epsilon |\vec{E}(\vec{r})|^2\}} \int d\omega \ e^{-i\omega t} \int d^3 \vec{k} \ e^{i\vec{k}\cdot\vec{r}} \frac{F(\omega,\vec{k})}{i\omega + D_T |\vec{k}|^2}.$$
 (S20)

We can then solve for the autocorrelation of $\delta \overline{T}$:

$$\langle \delta \bar{T}(t) \delta \bar{T}^{*}(t+\tau) \rangle = \frac{(\max\{\epsilon |\vec{E}(\vec{r})|^{2}\})^{-2}}{(2\pi)^{8} V_{\text{eff}}^{2}} \int d^{3} \vec{r}_{1} \ \epsilon(\vec{r}_{1}) |\vec{E}(\vec{r}_{1})|^{2} \int d^{3} \vec{r}_{2} \ \epsilon(\vec{r}_{2}) |\vec{E}(\vec{r}_{2})|^{2} \\ \times \int d\omega_{1} \ e^{-i\omega_{1}t} \int d\omega_{2} \ e^{i\omega_{2}(t+\tau)} \\ \times \int d^{3} \vec{k}_{1} \ e^{i\vec{k}_{1}\cdot\vec{r}_{1}} \int d^{3} \vec{k}_{2} \ e^{-i\vec{k}_{2}\cdot\vec{r}_{2}} \frac{\langle F(\omega_{1},\vec{k}_{1})F^{*}(\omega_{2},\vec{k}_{2})\rangle}{(i\omega_{1}+D_{T}|\vec{k}_{1}|^{2})(-i\omega_{2}+D_{T}|\vec{k}_{2}|^{2})}.$$
(S21)

Inputting the frequency-space autocorrelation of the Langevin driving force (compare Eqn. S13) [S5],

$$\langle F(\omega_1, \vec{k}_1) F^*(\omega_2, \vec{k}_2) \rangle = (2\pi)^4 \frac{2k_B T_0^2 D_T}{c_V} |\vec{k}|^2 \delta(\vec{k}_1 - \vec{k}_2) \delta(\omega_1 - \omega_2), \tag{S22}$$

and computing the remaining ω_1 integral, we can simplify to

$$\langle \delta \bar{T}(t) \delta \bar{T}^*(t+\tau) \rangle = \frac{(\max\{\epsilon |\vec{E}(\vec{r})|^2\})^{-2}}{(2\pi)^3 V_{\text{eff}}^2} \frac{k_B T_0^2}{c_V} \int \,\mathrm{d}^3 \vec{k} \,\, e^{-D_T |\vec{k}|^2 \tau} \left| \int \mathrm{d}^3 \vec{r} \,\, \epsilon(\vec{r}) |\vec{E}(\vec{r})|^2 e^{i\vec{k}\cdot\vec{r}} \right|^2. \tag{S23}$$

Eqn. S23 must equal Eqn. S1 for $\tau = 0$, which reveals the final solution for the thermal mode volume V_T :

$$V_{T} = \frac{(2\pi)^{3} V_{\text{eff}}^{2} (\max\{\epsilon | \vec{E}(\vec{r})|^{2}\})^{2}}{\int d^{3}\vec{r} \ \left(\int d^{3}\vec{r} \ \epsilon(\vec{r}) | \vec{E}(\vec{r})|^{2} e^{i\vec{k}\cdot\vec{r}}\right)^{2}} = \frac{V_{\text{eff}}^{2} (\max\{\epsilon | \vec{E}(\vec{r})|^{2}\})^{2}}{\int d^{3}\vec{r} \ \epsilon(\vec{r})^{2} | \vec{E}(\vec{r})|^{4}}$$
$$\therefore V_{T} = \frac{V_{\text{eff}}^{2}}{\frac{\int d^{3}\vec{r} \ \epsilon(\vec{r})^{2} | \vec{E}(\vec{r})|^{4}}{\max\{\epsilon^{2} | \vec{E}|^{4}\}}} = \frac{V_{\text{eff}}^{2}}{V_{\text{eff}}^{(2)}}$$
(S24)

where

$$V_{\rm eff}^{(2)} = \frac{\int d^3 \vec{r} \ \epsilon(\vec{r})^2 |\vec{E}(\vec{r})|^4}{\max\{\epsilon^2 |\vec{E}|^4\}}.$$
 (S25)

This result matches Gorodetsky's original result [S4] with the exception of different normalization conditions.

C. Comparison to Multi-mode Thermal Decay in a 2D PhC Slab

Under the single-mode approximation derived in the preceding sections, Eqn. S18 implies a Lorentzian TRN spectrum

$$S_{\omega\omega}(\omega) = \left(\frac{\omega_0}{n}\alpha_{\rm TO}\right)^2 \frac{k_B T_0^2}{c_V V_T} \frac{2\Gamma_T}{\Gamma_T^2 + \omega^2}.$$
(S26)

As noted in the main text, this approximate spectrum can be evaluated for any optical microcavity (photonic crystals, microtoroids, microbottles, ring resonators, micropillars, microdisks, and so on) independent of its exact confining geometry. This allows us to derive general noise limits as illustrated in the main text and derived in Section ID. If a particular experimental system is of interest, we can verify the accuracy of this approximation by solving the stochastic heat equation (Eqn. S7) for that particular cavity geometry. Here, since we measure TRN in high- Q/V_{eff} 2D slab photonic crystal cavities (see main text and supplement Section II), we demonstrate this evaluation for a Gaussian mode confined within an infinite two dimensional slab. The heat equation in this case lends logarithmically — as opposed to exponentially — decaying temperature fluctuations in time.

For a slab of thickness w lying atop the xy plane, the local temperature change $\delta T(\vec{r},t) = \sum_n T_n(\vec{r}_{\parallel},t)\phi_n(z)$ can be expanded in terms of the out-of-plane eigenfunctions, $\phi_n(z) = \cos(n\pi z/w)$ assuming insulating boundary conditions on the top and bottom of the slab. The stochastic heat equation then simplifies to the form

$$\frac{\partial T_n(\vec{r}_{\parallel},t)}{\partial t} = D_T \left[\nabla^2 - (n\pi/w)^2 \right] T_n(\vec{r}_{\parallel},t) + \frac{1}{w} \int \phi_n^*(z) F_T(\vec{r},t) \mathrm{d}z.$$
(S27)

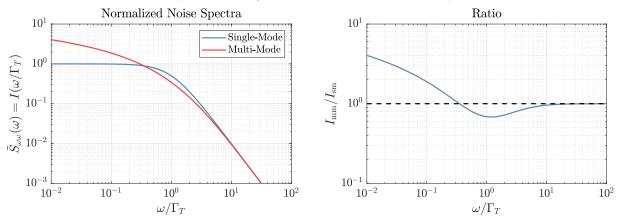


FIG. S1. Normalized noise spectra $\tilde{S}_{\omega\omega}(\omega) = I(\omega/\Gamma_T)$ for single-mode (Eqn. S32) and multi-mode (Eqn. S31) TRN in an infinite slab of finite thickness.

If assume a two-dimensional Gaussian mode profile

$$\epsilon(\vec{r})|\vec{E}(\vec{r})|^2 = \begin{cases} \frac{1}{2\pi\sigma^2} e^{-|\vec{r}_{\parallel}|^2/2\sigma^2} & 0 < z < w\\ 0 & \text{else} \end{cases},$$
(S28)

all $n \neq 0$ terms in the temperature expansion have zero contribution to the mode-averaged temperature fluctuation (Eqn. S6) of interest, which involves the integral $\int \phi_n(z) dz$. Eqn. S27 then simplifies to the two-dimensional form

$$\frac{\partial T(\vec{r}_{\parallel},t)}{\partial t} = D_T \nabla^2 T(\vec{r}_{\parallel},t) + F_T^{\parallel}(\vec{r}_{\parallel},t), \tag{S29}$$

where we have dropped the n = 0 subscript and introduced a modified fluctuation $F_T^{\parallel}(\vec{r}_{\parallel}, t)$ with statistics

$$\langle F_T^{\parallel *}(\vec{r}_{\parallel},t)F_T^{\parallel}(\vec{r}_{\parallel}',t')\rangle = \frac{1}{w^2} \int \mathrm{d}z \int \mathrm{d}z' \phi_0^*(z)\phi_0(z') \langle F_T^*(\vec{r},t)F_T(\vec{r}',t')\rangle = \frac{1}{w} \frac{2D_T k_B T_0^2}{c_V} \delta(t-t') \vec{\nabla}_{\vec{r}_{\parallel}} \cdot \vec{\nabla}_{\vec{r}_{\parallel}'} \delta(\vec{r}_{\parallel}-\vec{r}_{\parallel}).$$
(S30)

Comparing Eqns. S29, S30 to their three-dimensional analogs (Eqns. S7, S8), we see that projecting onto the n = 0 subspace reduces the finite-thickness slab to an infinite two-dimensional problem where F_T is scaled by $w^{-1/2}$. We can then apply the techniques of Section IB (expansion in Fourier normal modes) to solve for the spectrum of temperature (and therefore resonant frequency) fluctuations. Without inverse Fourier transforming frequency, Eqn. S21 gives

$$S_{\omega\omega}^{\rm mm}(\omega) = \left(\frac{\omega_0}{n}\alpha_{\rm TO}\right)^2 \frac{\langle \delta \bar{T}(\omega)\delta \bar{T}(\omega')\rangle}{\delta(\omega-\omega')} = 2\left(\frac{\omega_0}{n}\alpha_{\rm TO}\right)^2 \frac{k_B T_0^2}{w c_V} \int \frac{D_T k_{\parallel}^2}{(D_T k_{\parallel}^2)^2 + \omega^2} |\epsilon E^2(k_{\parallel})|^2 d^2 k_{\parallel}$$
$$S_{\omega\omega}^{\rm mm}(\omega) = \left(\frac{\omega_0}{n}\alpha_{\rm TO}\right)^2 \frac{k_B T_0^2}{2\pi w c_v D_T} \underbrace{\int_0^\infty \frac{x}{x^2 + (\omega\sigma^2/D_T)^2} e^{-x} dx}_{I_{\rm mm}(\omega\sigma^2/D_T)}$$
(S31)

with the change of variables $(k_{\parallel}\sigma)^2 \rightarrow x$. Note that we treat the effect of patterned holes in our experimental structures through a reduced thermal conductivity, and therefore thermal diffusivity, as a function of the slab porosity (see Section II for further detail). We can compare this result with the single-mode approximation, which (by evaluating Eqns. S16, S17 for the Gaussian mode profile in Eqn. S28) gives

$$V_T = 4\pi w \sigma^2 \quad \Gamma_T = \frac{D_T}{\sigma^2}, \quad \Rightarrow \quad S^{\rm sm}_{\omega\omega}(\omega) = \left(\frac{\omega_0}{n} \alpha_{\rm TO}\right)^2 \frac{k_B T_0^2}{2\pi w c_v D_T} \underbrace{\frac{1}{1 + (\omega \sigma^2/D_T)^2}}_{I_{\rm sm}(\omega \sigma^2/D_T)}.$$
(S32)

As expected, the integral $\int_{-\infty}^{\infty} S_{\omega\omega} d\omega/2\pi$ of either spectra yields $\langle \delta \omega^2 \rangle = (\omega_0 \alpha_{\rm TO}/n)^2 \langle \delta T^2 \rangle = (\omega_0 \alpha_{\rm TO}/n)^2 k_B T_0^2/c_V V_T$ in correspondence with Eqn. S1. Fig. S1 plots each normalized spectrum for comparison along with the ratio $I_{\rm mm}/I_{\rm sm}$. These results substantiate the claims in the main text: the single-mode approximation undershoots at low frequency $\omega \ll \Gamma_T$, slightly overshoots at intermediate frequencies $\omega \sim \Gamma_T$, and converges to the multi-mode spectrum at high frequencies $\omega \gg \Gamma_T$. We further note that the error of the multi-mode spectrum increases at low frequencies for any finite volume system: in our experiment, for example, the multi-mode estimate does not account for low frequency heat transfer through the underlying oxide around the released membrane. Thus, in the range of frequencies of interest (i.e. near the thermal cutoff frequency $\Gamma_T = D_T / \sigma^2$), single-mode thermal decay is an appropriate simplifying assumption that allows the thermal noise spectrum to be well-approximated irrespective of the cavity's exact geometry.

D. Derivation of Driven Cavity Dynamics

To determine the practical impact of thermo-refractive noise on microcavity dynamics, we now consider the case of a cavity driven by a monochromatic laser with frequency ω_L . Intuitively, we would expect that the large (relative to the cavity linewidth), fast (relative to the cavity decay time) stochastic deviations of the resonance frequency in the high- Q/V_{eff} limit would restrict the maximum intensity in the cavity, as a narrow linewidth laser would no longer always be on resonance with the fluctuating cavity resonance. A mode volume-dependent maximum "effective" quality factor describing the stored energy should result. A similar effective quality factor could be derived if the coherence of the intracavity field — rather than the stored energy alone — is also of interest.

To prove these suppositions, we solve the driven temporal coupled mode theory relation

$$\frac{\mathrm{d}a(t)}{\mathrm{d}t} = \left[i\omega_0(t) - \Gamma_l\right]a(t) + i\sqrt{2\Gamma_c}s_{\mathrm{in}}(t),\tag{S33}$$

for the cavity field a(t), where $\omega_0(t) = \omega_0 + \delta\omega(t)$ is the instantaneous resonant frequency, $\Gamma_l = \langle \omega_0(t) \rangle / 2Q_l$ is the amplitude decay rate of a corresponding to a loaded quality factor Q_l , and Γ_c is the amplitude coupling rate of the drive field $s_{in}(t) = \tilde{s}_{in}e^{i\omega_L t} + c.c.$, detuned from resonance by $\Delta = \omega_L - \omega_0$. In the presence of TRN, $\delta\omega(t)$ is non-Markovian, zero-mean Gaussian noise with the autocorrelation given by Eqn. S18. Solving with an integrating factor and introducing the slowly varying cavity amplitude $\tilde{a}(t) = a(t)e^{-i\omega_0 t}$ in a reference frame co-rotating with the static cavity resonance, we find

$$\tilde{a}(t) = i\sqrt{2\Gamma_c}\tilde{s}_{\rm in} \int_{-\infty}^t \mathrm{d}t' e^{-(i\Delta + \Gamma_l)(t-t')} e^{-i\int_{t'}^t \mathrm{d}t''\delta\omega(t'')}.$$
(S34)

Since the steady state solution is desired, we assume that the integration starts at $t = -\infty$ such that the system has no "memory" of the initial conditions. Using Eqn. S34, we can compute $\langle \tilde{a}(t) \rangle$ and $\langle |\tilde{a}(t)|^2 \rangle$, the mean cavity field amplitude and stored energy, respectively. In certain limiting cases, the noise spectrum $S_{aa}(\omega)$ of the intra-cavity field can also be derived.

1. Cavity Spectrum in the Perturbative Limit

One of these limiting cases is the perturbative regime commonly studied in the literature for low- Q/V_{eff} cavities, wherein $\delta\omega_{\text{rms}} \ll \Gamma_l$. In this case, $\tilde{a}(t)$ and $\delta\omega(t)$ — described by (from Eqns. S9, S14)

$$\frac{\mathrm{d}\,\delta\omega(t)}{\mathrm{d}t} = -\Gamma_T\delta\omega(t) + \delta\omega_{\mathrm{rms}}\sqrt{2\Gamma_T}W(t) \tag{S35}$$

for a Wiener process W(t) with $\langle W(t)W(t')\rangle = \delta(t-t')$ — can be expanded in orders of $\delta\omega_{\rm rms}\sqrt{2\Gamma_T}$. The zerothand first-order evolution equations (with subscripts 0 and 1, respectively) are

$$\frac{\mathrm{d}\tilde{a}_{0}(t)}{\mathrm{d}t} = [i(\delta\omega_{0}(t) + \Delta) - \Gamma_{l}]\tilde{a}_{0}(t) + \sqrt{2\Gamma_{l}}\tilde{s}_{\mathrm{in}} \qquad \frac{\mathrm{d}\delta\omega_{0}(t)}{\mathrm{d}t} = -\Gamma_{T}\delta\omega_{0}(t) \tag{S36}$$

$$\frac{\mathrm{d}\tilde{a}_{1}(t)}{\mathrm{d}t} = [i(\delta\omega_{0}(t) + \Delta) - \Gamma_{l}]a_{1}(t) + i\delta\omega_{1}(t)\tilde{a}_{0}(t) \qquad \qquad \frac{\mathrm{d}\delta\omega_{1}(t)}{\mathrm{d}t} = -\Gamma_{T}\delta\omega_{1}(t) + \delta\omega_{\mathrm{rms}}\sqrt{2\Gamma_{T}}W(t). \tag{S37}$$

Solving in the frequency domain yields

$$\tilde{a}_{1}(\omega) = \frac{\sqrt{2\Gamma_{l}}\tilde{s}_{\rm in}}{\Gamma_{l} - i\Delta} \frac{i\delta\omega_{\rm rms}\sqrt{2\Gamma_{T}}W(\omega)}{(\Gamma_{T} - i\omega)[\Gamma_{l} + i(\omega - \Delta)]},\tag{S38}$$

corresponding to the frequency spectrum

$$S_{aa}(\omega) = \langle \tilde{a}_1(\omega)^* \tilde{a}_1(\omega) \rangle = \frac{2\Gamma_l |\tilde{s}_{\rm in}|^2}{\Gamma_l^2 + \Delta^2} \frac{2\Gamma_T \delta \omega_{\rm rms}^2}{(\Gamma_T^2 + \omega^2)(\Gamma_l^2 + (\omega - \Delta)^2)}.$$
(S39)

The intra-cavity noise spectrum can therefore be approximated as the product of two Lorentzians with spectral widths $2\Gamma_T$ and $2\Gamma_l$. When $\Gamma_T \ll \Gamma_l$, which often coincides with the perturbative limit $\delta\omega_{\rm rms} \ll \Gamma_l$ for large mode volumes $(\delta\omega_{\rm rms} \propto V_T^{-1/2} \text{ and } \Gamma_T \propto V_T^{-2/3} \text{ for a three-dimensional Gaussian mode})$, the resonant frequency fluctuations are small and occur over timescales much longer than that of intra-cavity photon decay. TRN thus leads to a weak inhomogeneous broadening of the resonant mode that can often be neglected for common applications of low- $Q/V_{\rm eff}$ optical cavities. Gravitational wave interferometry [S5, S6] and ultra-stable optical frequency references [S7, S8] are two notable exceptions that have led to significant interest in perturbative TRN.

2. General Derivation for $\langle \tilde{a}(t) \rangle$

Our work focuses on the transition to non-perturbative TRN in high- Q/V_{eff} microcavities, where we are interested in general solutions for the statistical moments of Eqn. S34 in the presence of TRN. Specifically, $\langle \tilde{a}(t) \rangle$ provides insight into thermal noise-induced dephasing while $\langle \tilde{a}^2(t) \rangle$ lends a bound on the maximum allowable stored energy.

The expected intra-cavity field amplitude

$$\langle \tilde{a}(t) \rangle = i \sqrt{2\Gamma_c} \tilde{s}_{\rm in} \int_{-\infty}^t dt' e^{-(i\Delta + \Gamma_l)(t-t')} \langle e^{-\int_{t'}^t dt'' i\delta\omega(t'')} \rangle \tag{S40}$$

follows directly from Eqn. S34, where the average on the right-hand side has a similar form to the characteristic functional [S9]

$$\Phi[k(t)] = \langle e^{i \int k(t)f(t)dt} \rangle = \frac{\int e^{i \int k(t)f(t)dt} P[f(t)]\mathcal{D}f(t)}{\int P[f(t)]\mathcal{D}f(t)},$$
(S41)

a normalized average of $e^{i \int k(t)f(t)dt}$ along the paths f(t) with respective probabilities P[f(t)]. For the special case of Gaussian noise, the moment-generating properties of the characteristic functional allow Eqn. S41 to be simplified to

$$\Phi[k(t)] = e^{i\int k(t)M(t)dt}e^{-1/2\int dt\int dt'k(t)k(t')\langle f(t)f(t')\rangle},$$
(S42)

which is characterized by two parameters only: 1) the mean path M(t), and the autocorrelation of the noise f(t), $\langle f(t)f(t+t')\rangle$. Comparing Eqn. S40 to Eqn. S41, we find $k(t'') = \begin{cases} 1 & t' < t'' < t \\ 0 & \text{else} \end{cases}$ and $f(t) = \delta\omega(t'')$. Since $\langle \omega_0(t) \rangle = 0$,

$$\langle e^{-\int_{t'}^{t} \mathrm{d}t'' i\delta\omega(t'')} \rangle = \exp\left[-\frac{1}{2}\int_{t'}^{t} \mathrm{d}t'_{2}\int_{t'}^{t} \mathrm{d}t''_{2}\delta\omega_{\mathrm{rms}}^{2}e^{-\Gamma_{T}|t''_{2}-t'_{2}|}\right]$$

$$= \exp\left[-\int_{0}^{t-t'} \mathrm{d}\tau(t-t'-\tau)\delta\omega_{\mathrm{rms}}^{2}e^{-\Gamma_{T}|\tau|}\right]$$

$$\langle e^{-\int_{t'}^{t} \mathrm{d}t'' i\delta\omega(t'')} \rangle = \exp\left[\frac{\delta\omega_{\mathrm{rms}}^{2}}{\Gamma_{T}^{2}}\left(1-\Gamma_{T}(t-t')-e^{-\Gamma_{T}(t-t')}\right)\right].$$
(S43)

Combined with the substitution $\tilde{\tau} = (\delta \omega_{\rm rms} / \Gamma_T)^2 e^{-\Gamma_T (t-t')}$, Eqn. S43 simplifies to

$$\langle \tilde{a}(t) \rangle = i \frac{\sqrt{2\Gamma_c} \tilde{s}_{\rm in}}{\Gamma_T} e^{(\delta\omega_{\rm rms}/\Gamma_T)^2} \left(\frac{\delta\omega_{\rm rms}}{\Gamma_T}\right)^2 \left(\frac{-i\Delta - \Gamma_l - \delta\omega_{\rm rms}^2/\Gamma_T}{\Gamma_T}\right] \int_0^{(\delta\omega_{\rm rms}/\Gamma_T)^2} \tilde{\tau} \frac{i\Delta + \Gamma_l + \delta\omega_{\rm rms}^2/\Gamma_T}{\Gamma_T} - 1 e^{-\tilde{\tau}} d\tilde{\tau}, \tag{S44}$$

which is in the form of the lower incomplete Gamma function

$$\gamma_l(s,x) = \int_0^x \tilde{\tau}^{s-1} e^{-\tilde{\tau}} \mathrm{d}\tilde{\tau}.$$
 (S45)

The final closed-form solution is therefore

$$\langle \tilde{a}(t) \rangle = i \frac{\sqrt{2\Gamma_c} \tilde{s}_{\rm in}}{\Gamma_T} e^x x^{-s} \gamma_l(s, x) \tag{S46}$$

$$x \equiv \left(\frac{\delta\omega_{\rm rms}}{\Gamma_T}\right)^2 \tag{S47}$$

$$s \equiv \frac{\Gamma_l + i\Delta}{\Gamma_T} + x. \tag{S48}$$

To confirm this solution, we can evaluate the limiting case of $\delta \omega_{\rm rms} \to 0$ $(x \to 0)$, corresponding to a noiseless thermal reservoir when $T \to 0$. Using the series expansion of $\gamma_l(s, x)$ in terms of s, x and the standard Gamma function $\gamma_f(z)$, we find

$$\begin{aligned} \langle |\tilde{a}(t)| \rangle_{T=0} &= \lim_{x \to 0} i \frac{\sqrt{2\Gamma_c} \tilde{s}_{in}}{\Gamma_T} e^x x^{-s} \left[x^s e^{-x} \gamma_f(s) \sum_{k=0}^{\infty} \frac{x^k}{\gamma_f(s+k+1)} \right] \\ &= i \frac{\sqrt{2\Gamma_c} \tilde{s}_{in}}{\Gamma_T} \frac{\gamma_f(s)}{\gamma_f(s+1)} \\ \langle |\tilde{a}(t)| \rangle_{T=0} &= i \frac{\sqrt{2\Gamma_c} \tilde{s}_{in}}{\Gamma_T} \frac{1}{s} \Big|_{x=0} = i \frac{\sqrt{2\Gamma_c} \tilde{s}_{in}}{\Gamma_l + i\Delta}, \end{aligned}$$
(S49)

as expected from standard (noiseless) temporal coupled mode theory.

Assuming critical coupling ($\Gamma_c = \Gamma_l/2$) and resonant excitation ($\delta = 0$), we find the "effective" quality factor

$$Q_{\text{eff}} = \frac{\omega_0 |\langle \tilde{a}(t) \rangle|^2}{2|\tilde{s}_{\text{in}}|^2} = Q_l \left(\frac{\Gamma_l}{\Gamma_T}\right)^2 e^{2x} x^{-2s} \gamma_l^2(s, x) \tag{S50}$$

by analogy to the noiseless result where $Q = \omega_0 \langle |\tilde{a}(t)| \rangle_{T=0}^2 / 2|\tilde{s}_{\rm in}|^2$.

This result is used in the main text to describe dephasing in the qubit limit of cavity nonlinear optics. For a given mode volume, the optimum loaded quality factor $Q_l^{\text{opt}} \approx \omega_0 \Gamma_T / 2\delta \omega_{\text{rms}}^2$ (assuming $\delta \omega_{\text{rms}} \ll \Gamma_T$, which is valid for the range of mode volumes plotted in Fig. 4 of the main text) maximizes the resonant cavity amplitude: lower quality factors incur excess loss, whereas higher quality factors allow the qubit to "explore" a larger region of the phase space, thereby decaying the integrated cavity amplitude. Intuitively, the resulting maximum amplitude $\langle |\tilde{a}(t)| \rangle$ increases with increasing mode volume due to the reduced magnitude of temperature fluctuations.

3. General Derivation for $\langle \tilde{a}^2(t) \rangle$

Solving for $\langle \tilde{a}(t)^2 \rangle$ generally follows the same procedure, and reveals a limit on the allowable intra-cavity optical energy in the presence of TRN. Starting from Eqn. S34, the autocorrelation of \tilde{a} takes the form

$$\langle \tilde{a}(t)\tilde{a}^*(0)\rangle = 2\Gamma_c |\tilde{s}_{\rm in}|^2 \int_{-\infty}^t \mathrm{d}t' e^{-(i\Delta + \Gamma_l)(t-t')} \int_{-\infty}^0 \mathrm{d}t'' e^{-(i\Delta - \Gamma_l)t''} \langle e^{\int_{t'}^t i\delta\omega(t_2)\mathrm{d}t_2 - \int_{t''}^0 i\delta\omega(t_2)\mathrm{d}t_2} \rangle. \tag{S51}$$

Following the method of [S10], the average can be expressed in the form of Eqn. S41,

$$\langle e^{\int_{t'}^{t} i\delta\omega(t_2)dt_2 - \int_{t''}^{0} i\delta\omega(t_2)dt_2} \rangle = \langle e^{i\int_{-\infty}^{\infty} k(t_2)\delta\omega(t_2)dt_2} \rangle = e^{-1/2\int_{-\infty}^{\infty} dt'_2 \int_{-\infty}^{\infty} dt''_2 k(t'_2)k(t''_2)\langle\delta\omega(t'_2)\delta\omega(t''_2)\rangle}, \tag{S52}$$

by appropriately defining k(t). As illustrated in Fig. S2, the dependence of $k(t_2)$ upon t', t", and t differs in three sectors of the region of integration. Simple diagrams in each of the three scenarios can be used to show

$$k_1(t_2) = \begin{cases} 1, & t' \le t_2 \le t'' \\ 1, & 0 \le t_2 \le t \\ 0, & \text{else} \end{cases} \quad k_2(t_2) = \begin{cases} -1, & t'' \le t_2 \le t' \\ 1, & 0 \le t_2 \le t \\ 0, & \text{else} \end{cases} \quad k_3(t_2) = \begin{cases} -1, & t'' \le t_2 \le 0 \\ 1, & t' \le t_2 \le t \\ 0, & \text{else} \end{cases}$$
(S53)

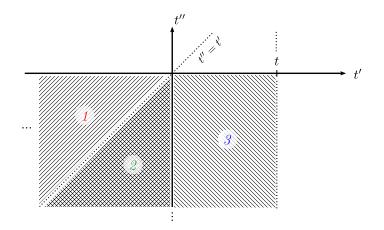


FIG. S2. The complete region of integration can be divided into three sub-spaces which yield different conditions for k(t).

Combining these conditions with those of each region, we find a closed form for k(t):

$$k(t_2) = \begin{cases} \operatorname{sign}(t'' - t'), & t' < 0 \& \min(t', t'') \le t_2 \le \max(t', t'') \\ 1, & (t' < 0 \& 0 \le t_2 \le t) \mid | (t' > 0 \& t' \le t_2 \le t) \\ -1, & t' > 0 \& t'' \le t_2 \le 0 \\ 0, & \text{else.} \end{cases}$$
(S54)

This definition allows us to rewrite the autocorrelation as

$$\mathcal{R}_{aa}(t) = \langle \tilde{a}(t)\tilde{a}^{*}(t+\tau)\rangle = 2\Gamma_{c}|\tilde{s}_{\mathrm{in}}|^{2} \int_{-\infty}^{t} \mathrm{d}t' e^{-(i\Delta+\Gamma_{l})(t-t')} \int_{-\infty}^{0} \mathrm{d}t'' e^{-(i\Delta-\Gamma_{l})t''} \\ \times \exp\left[-\frac{1}{2} \int_{-\infty}^{\infty} \mathrm{d}t'_{2} \int_{-\infty}^{\infty} \mathrm{d}t''_{2} k(t'_{2}) k(t''_{2}) \delta\omega_{\mathrm{rms}}^{2} e^{-\Gamma_{T}|t'_{2}-t''_{2}|}\right].$$
(S55)

While a general solution to the full autocorrelation in Eqn. S55 appears intractable, we can find $\langle |\tilde{a}|^2 \rangle = \langle |\tilde{a}(0)|^2 \rangle$ by evaluating Eqn. S55 at t = 0 (thereby eliminating integration region #3 in Fig. S2), which yields

$$\langle |\tilde{a}|^{2} \rangle = 2\Gamma_{c} |\tilde{s}_{\rm in}|^{2} \int_{-\infty}^{0} dt' e^{(i\Delta + \Gamma_{l})t'} \int_{-\infty}^{0} dt'' e^{-(i\Delta - \Gamma_{l})t''} \\ \times \begin{cases} \exp\left[\left(\frac{\delta\omega_{\rm rms}}{\Gamma_{T}}\right)^{2} \left(1 - \Gamma_{T}(t'' - t') - e^{-\Gamma_{T}(t'' - t')}\right)\right], & \text{Region 1} (t' < 0 \& t'' > t') \\ \exp\left[\left(\frac{\delta\omega_{\rm rms}}{\Gamma_{T}}\right)^{2} \left(1 - \Gamma_{T}(t' - t'') - e^{-\Gamma_{T}(t'' - t'')}\right)\right], & \text{Region 2} (t' < 0 \& t' > t'') \end{cases}$$
(S56)

Note that the result in either region is nearly the same – exchanging t' and t'' in either region returns the integral for the other region, but conjugates $i\Delta$. Therefore, we focus on evaluating Eqn. S56 in Region 1, and then generalize this result to the other region by taking the complex conjugate. In Region 1, the substitution $\tilde{\tau} = (\delta \omega_{\rm rms}/\Gamma_T)^2 \exp\left[-\Gamma_T (t'' - t')\right]$ yields

$$\langle |\tilde{a}(0)|^{2} \rangle_{1} = 2\Gamma_{c} |\tilde{s}_{\rm in}|^{2} \int_{-\infty}^{0} dt' e^{2\Gamma_{l}t'} \int_{t'}^{0} dt'' e^{(-i\Delta + \Gamma_{l})(t'' - t')} \exp\left[\left(\frac{\delta\omega_{\rm rms}}{\Gamma_{T}}\right)^{2} \left(1 - \Gamma_{T}(t'' - t') - e^{-\Gamma_{T}(t'' - t')}\right)\right]$$

$$= 2\Gamma_{c} |\tilde{s}_{\rm in}|^{2} \int_{-\infty}^{0} dt' e^{2\Gamma_{l}t'} \frac{e^{x}}{\Gamma_{T}} x^{-s'} \int_{xe^{\Gamma_{T}t'}}^{x} \tilde{\tau}^{s'-1} e^{-\tilde{\tau}} d\tilde{\tau}$$

$$\langle |\tilde{a}(0)|^{2} \rangle_{1} = 2\Gamma_{c} |\tilde{s}_{\rm in}|^{2} \frac{e^{x}}{\Gamma_{T}} x^{-s'} \int_{-\infty}^{0} dt' e^{2\Gamma_{l}t'} \left[\gamma_{l}(s', x) - \gamma_{l}(s', xe^{\Gamma_{T}t'})\right]$$

$$(S57)$$

where $x = (\delta \omega_{\rm rms}/\Gamma_T)^2$ and $s' = (\delta \omega_{\rm rms}^2/\Gamma_T - \Gamma_l + i\Delta)/\Gamma_T$. The first term can be directly evaluated, while the second can be simplified with integration by parts using the relationship

$$\frac{\partial \gamma_l(s',x)}{\partial x} = x^{s'-1} e^{-x}.$$
(S58)

With a second substitution $\tilde{\tau}_2 = x e^{\Gamma_T t'}$ we find

$$\langle |\tilde{a}(0)|^2 \rangle_1 = 2\Gamma_c |\tilde{s}_{\rm in}|^2 \frac{e^x}{\Gamma_T} x^{-s'} \left[\frac{\gamma_l(s',x)}{2\Gamma_l} - \frac{x^{-\frac{2\Gamma_l}{\Gamma_T}}}{\Gamma_T} \int_0^x \tilde{\tau}_2^{\frac{2\Gamma_l}{\Gamma_T} - 1} \gamma_l(s',\tilde{\tau}_2) \mathrm{d}\tilde{\tau}_2 \right]$$

$$= 2\Gamma_c |\tilde{s}_{\rm in}|^2 \frac{e^x}{\Gamma_T} x^{-s'} \left\{ \frac{\gamma_l(s',x)}{2\Gamma_l} - \frac{x^{-\frac{2\Gamma_l}{\Gamma_T}}}{\Gamma_T} \left(\frac{\Gamma_T}{2\Gamma_l}\right) \left[\tilde{\tau}_2^{\frac{2\Gamma_l}{\Gamma_T}} \gamma_l(s',\tilde{\tau}_2) + \gamma_u(s' + \frac{2\Gamma_l}{\Gamma_T},\tilde{\tau}_2) \right]_{\tilde{\tau}_2 = 0}^{\tilde{\tau}_2 = x} \right\}$$

$$(S59)$$

where $\gamma_u(s', x)$ is the upper incomplete Gamma function defined by

$$\gamma_u(s',x) = \int_x^\infty \tau^{s'-1} e^{-\tau} d\tau.$$
(S60)

Evaluating the final terms, the result simplifies nicely to

$$\langle |\tilde{a}(0)|^2 \rangle_1 = \Gamma_c |\tilde{s}_{\rm in}|^2 \frac{e^x x^{-s'}}{\Gamma_T \Gamma_l} \left\{ \gamma_l(s', x) - \left[\gamma_l(s, x) - x^{\frac{2\Gamma_l}{\Gamma_T}} \gamma_l(s' + \frac{2\Gamma_l}{\Gamma_T}, x) \right] \right\}$$

$$= \frac{|\tilde{s}_{\rm in}|^2}{\Gamma_T} \left(\frac{\Gamma_c}{\Gamma_l} \right) e^x x^{-(s' + \frac{2\Gamma_l}{\Gamma_T})} \gamma_l(s' + \frac{2\Gamma_l}{\Gamma_T}, x)$$
(S61)

To find the complete result, we simply add the second term in Eqn. S56 to find

$$\langle |\tilde{a}|^2 \rangle = \frac{|\tilde{s}_{\rm in}|^2}{\Gamma_T} \left(\frac{\Gamma_c}{\Gamma_l}\right) e^x \left[x^{-s} \gamma_l(s,x) + x^{-s^*} \gamma_l(s^*,x) \right]$$
(S62)

$$x \equiv \left(\frac{\delta\omega_{\rm rms}}{\Gamma_T}\right)^2 \tag{S63}$$

$$s \equiv \frac{\Gamma_l + i\Delta}{\Gamma_T} + x. \tag{S64}$$

Note the similarity to Eqns. S46-S48. Once again, we must ensure that our solution corresponds to the noiseless result expected when $\delta\omega_{\rm rms} \to 0$. Using the series expansion of $\gamma_l(s, x)$, we find

$$\langle |\tilde{a}|^2 \rangle_{T=0} = \lim_{x \to 0} \frac{|\tilde{s}_{in}|^2}{\Gamma_T} \left(\frac{\Gamma_c}{\Gamma_l}\right) e^x \left[x^{-s} \gamma_l(s,x) + x^{-s^*} \gamma_l(s^*,x)\right]$$

$$= \frac{|\tilde{s}_{in}|^2}{\Gamma_T} \left(\frac{\Gamma_c}{\Gamma_l}\right) \left[\frac{\gamma_f(s|_{x=0})}{\gamma_f(s|_{x=0}+1)} + \frac{\gamma_f(s^*|_{x=0})}{\gamma_f(s^*|_{x=0}+1)}\right]$$

$$= \frac{|\tilde{s}_{in}|^2}{\Gamma_T} \left(\frac{\Gamma_c}{\Gamma_l}\right) \left[\frac{\Gamma_T}{\Gamma_l + i\Delta} + \frac{\Gamma_T}{\Gamma_l - i\Delta}\right]$$

$$\langle |\tilde{a}|^2 \rangle_{T=0} = \frac{2\Gamma_c |\tilde{s}_{in}|^2}{\Delta^2 + \Gamma_l^2}$$
(S65)

as expected. Similar to the solution for $\langle \tilde{a}(t) \rangle$, we define the effective quality factor

$$Q_{\text{eff}} = \frac{\omega_0 |\langle \tilde{a}(t) \rangle|^2}{2|\tilde{s}_{\text{in}}|^2} = \frac{\omega_0}{2\Gamma_T} e^x x^{-s} \gamma_l(s, x)$$
(S66)

for resonant excitation ($\Delta = 0$) and critical coupling ($\Gamma_c = \Gamma_l/2$).

As opposed to the non-monotonic scaling of the mean field amplitude $\langle |\tilde{a}(t)| \rangle$ with Q_l , the stored energy $\langle |\tilde{a}(t)|^2 \rangle$ increases monotonically with increasing Q_l . This is intuitively described in the main text: continuing to increase Q_l decreases the cavity linewidth until Q_{eff} is saturated by mode volume-dependent thermal noise in the high- Q_l/V_{eff} regime. Finally, we note that the maximum energy storage (although not necessarily the maximum intensity, which also depends on the mode volume) is a achieved with large mode volumes due to reduced thermo-optic noise.

4. Cavity Spectrum in the White Noise Limit

The complete field autocorrelation $\mathcal{R}_{aa}(t)$ in Eqn. S55 simplifies considerably in the high- Q_l limit where $\Gamma_T \gg \Gamma_l$, as the cavity resonant frequency $\omega_0(t)$ can be assumed to directly track the temperature noise over the relevant timescales. The frequency noise is then effectively delta-correlated in time, and the aforementioned — albeit tedious — "integration by regions" technique can then be similarly applied to solve for the field noise spectrum $S_{aa}(\omega)$. A more intuitive approach to this solution is though adiabatic elimination of $\omega_0(t)$'s dynamics following the procedure in [S11]. Converting the optical field and resonant frequency evolution equations (Eqns. S33, S35) into stochastic differential equations yields

$$d\tilde{a}(t) = \left\{ \left[i(\delta\omega(t) + \Delta) - \Gamma_l \right] \tilde{a}(t) + \sqrt{2\Gamma_c} \tilde{s}_{\rm in} \right\} dt \qquad d\delta\omega(t) = -\Gamma_T \delta\omega(t) dt + \delta\omega_{\rm rms} \sqrt{2\Gamma_T} dW(t)$$
(S67)

for both Itô and Stratonovich forms since the frequency noise is additive $(\delta \omega_{\rm rms} \sqrt{2\Gamma_T}$ is constant). In the limit $\Gamma_T \to \infty$, we can adiabatically eliminate the resonant frequency dynamics, yielding a steady state value $\delta \omega(t) = \sqrt{2/\Gamma_T} \delta \omega_{\rm rms} dW(t)/dt$. The cavity evolution can then be simplified to

$$d\tilde{a}_{S}(t) = \left[(i\Delta - \Gamma_{l})\tilde{a}_{S}(t) + \sqrt{2\Gamma_{c}}\tilde{s}_{\rm in} \right] dt + \sqrt{\frac{2}{\Gamma_{T}}}\delta\omega_{\rm rms}\tilde{a}_{S}(t)dW(t)$$
(S68)

$$d\tilde{a}_{I}(t) = \left\{ \left[i\Delta - \left(\Gamma_{l} + \frac{\delta\omega_{\rm rms}^{2}}{\Gamma_{T}}\right) \right] \tilde{a}_{I}(t) + \sqrt{2\Gamma_{c}}\tilde{s}_{\rm in} \right\} dt + \sqrt{\frac{2}{\Gamma_{T}}}\delta\omega_{\rm rms}\tilde{a}_{I}(t)dW(t)$$
(S69)

in Stratonovich and Itô forms, respectively. Applying the Itô rule $(dW(t))^2 = dt$ to the latter, we can solve for the steady-state moments

$$\langle \tilde{a}(t) \rangle = \frac{\sqrt{2\Gamma_c} \tilde{s}_{\rm in}}{\left[\Gamma_l + \delta \omega_{\rm rms}^2 / \Gamma_T\right] - i\Delta} \qquad \qquad \langle |\tilde{a}(t)|^2 \rangle = \frac{2\left(\Gamma_c + \delta \omega_{\rm rms}^2 / \Gamma_T\right) \tilde{s}_{\rm in}}{\left[\Gamma_l + \delta \omega_{\rm rms}^2 / \Gamma_T\right]^2 + \Delta^2} \tag{S70}$$

which by comparison to Eqn. S49 and Eqn. S65 immediately reveals a thermal broadening $2\Gamma_l \rightarrow 2\Gamma_l + 2\delta\omega_{\rm rms}^2/\Gamma_T$ of the microcavity linewidth. We can also derive an equation of motion for the autocorrelation,

$$\frac{\mathrm{d}}{\mathrm{d}\tau} \langle \tilde{a}^*(t+\tau)\tilde{a}(t)\rangle = \left[i\Delta - \left(\Gamma_l + \frac{\delta\omega_{\mathrm{rms}}^2}{\Gamma_T}\right)\right] \langle \tilde{a}^*(t+\tau)\tilde{a}(t)\rangle + \sqrt{2\Gamma_c}\tilde{s}_{\mathrm{in}}\langle \tilde{a}(t)\rangle.$$
(S71)

Solving Eqn. S71 subject to the $\tau = 0$ conditions of Eqn. S70, we find

$$R_{aa}(t) = \frac{2\delta\omega_{\rm rms}^2 |s_{\rm in}|^2 / \Gamma_T}{\left[\Gamma_l + \delta\omega_{\rm rms}^2 / \Gamma_T\right]^2 + \Delta^2} e^{-\left(i\Delta + \Gamma_l + \delta\omega_{\rm rms}^2 / \Gamma_T\right)t},\tag{S72}$$

corresponding to the optical noise spectrum

$$S_{aa}(\omega) = \frac{2\delta\omega_{\rm rms}^2 |s_{\rm in}|^2 / \Gamma_T}{\left[\Gamma_l + \delta\omega_{\rm rms}^2 / \Gamma_T\right]^2 + \Delta^2} \frac{2(\Gamma_l + \delta\omega_{\rm rms}^2 / \Gamma_T)}{(\Gamma_l + \delta\omega_{\rm rms}^2 / \Gamma_T)^2 + (\omega - \Delta)^2}.$$
(S73)

Eqn. S73 evaluated in the perturbative limit $\delta \omega_{\rm rms} \ll \Gamma_l$ coincides with the low-frequency ($\omega \ll \Gamma_T$) limit of the previous perturbative spectrum (Eqn. S39).

II. EXPERIMENTAL TRN IN PHOTONIC CRYSTAL CAVITIES

The single-mode thermal decay approximation made in Eqn. S9 implies the decay rate of Eqn. S17 and the spectral density of cavity resonant frequency in Eqn. S26. This result is commonly used as a simplifying assumption for temperature fluctuations [S12, S13]; however, it is not immediately clear that the single-mode approximation holds in the case of small mode volume optical microcavities, where the characteristic length scales of the near diffraction-limited optical mode ($\sim \lambda/n$) can approach the phonon mean free paths [S14]. In absence of any experimental data in the literature to verify the assumption, we constructed an experiment to measure thermo-refractive noise in high- Q_l/V_{eff} silicon photonic crystal cavities. The experiment also allows us to compare measured TRN with the spectra derived from our multi-mode theory (Section IC) or computed through finite-element Fluctuation-Dissipation simulations (Section II F).

A. Photonic Crystal Cavity Sample Details

The L3 and L4/3 photonic crystal cavities were fabricated by Applied Nanotools foundry via electron-beam patterning and dry-etching of 220 nm-thick undoped silicon-on-insulator wafers with a 2 µm-thick buried oxide layer. To suspend the devices, the buried oxide was subsequently released via a 60 second timed wet etch in 49% hydrofluoric (HF) acid. The designs were adapted from Refs. [S15, S16]. As shown in Fig. 2 of the main text, superimposed gratings were added to improve vertical coupling efficiency. The gratings are formed via periodic hole radii perturbations ranging from $\Delta r = 0 \rightarrow 0.05r$ at a period equal to twice the lattice constant *a*. Although devices with quality factors as large as 600,000 were measured for small values of Δr , the results presented in the main text use $\Delta r = 0.05r$, which significantly improves collection efficiency into our fiber-coupled detector.

B. Experimental Setup

A more detailed version of the experimental setup depicted in the main text is provided in Fig. S3. The setup consists of a typical polarized light microscope, where the signal reflected from a PhC cavity is measured with balanced homodyne detection. The homodyne detector is balanced to quadrature by zeroing the DC component of

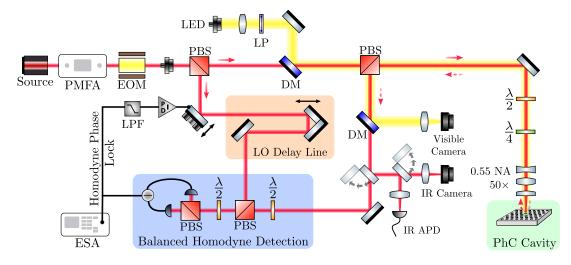


FIG. S3. Schematic of the setup built to measure TRN in photonic crystal cavities. An amplified (PriTel PMFA) continuous wave laser (Santec TSL-710) is separated into a local oscillator and cavity signal by a polarizing beamsplitter (PBS). The LO line is passively path-length matched to the cavity signal using a tunable retroreflector delay line. The cavity signal is combined with a linearly polarized (LP) white light source (LED) using a dichroic mirror (DM) and is reflected from a PhC cavity rotated 45° from the incident polarization (adjustable with a half-wave plate, $\lambda/2$), which allows the cavity signal to be isolated from the specular reflection using a PBS. A quarter-wave plate ($\lambda/4$) allows the specular reflection to be extracted for comparison to the cavity-only reflection. The reflected illumination light is separated and imaged onto a silicon CCD. The cavity signal can be directed with flip-mirrors towards an IR camera for imaging, an IR avalanche photodetector (ThorLabs PDB410C 10 MHz InGaAs APD) to collect low-noise reflection spectra, or towards the balanced homodyne detector. For the latter, a balanced photodetector (ThorLabs PDB480C-AC 1.6 GHz InGaAs p-i-n Photodetector) measures the homodyne signal from the recombined cavity reflection and local oscillator, and the result is recorded on an electronic spectrum analyzer (ESA; Agilent N9010A EXA Signal Analyzer). The DC signal extracted from a low-pass filter (LPF) is used as the feedback signal for a digital PID controller which stabilizes the signal-LO phase difference by actuating a piezo-actuated mirror. An electro-optic modulator (EOM) provides a known phase noise which can be used to calibrate the frequency noise of the PhC cavity. The sample stage is temperature-stabilized to $\Delta T < 0.01$ K using a peltier plate and a feedback temperature controller.

the homodyne signal with a digital PID feedback controller connected to a piezo-actuated mirror. In this configuration, the homodyne voltage signal

$$v_h \sim |\tilde{a}_{\rm LO}| |\tilde{a}_{\rm cavity}| \sin(\delta\phi_{\rm cavity}(t) + \phi_{\rm cavity}^0 - \phi_{\rm LO}) = |\tilde{a}_{\rm LO}| |\tilde{a}_{\rm cavity}| \delta\phi_{\rm cavity}(t)$$
(S74)

for a local oscillator signal $\tilde{a}_{\text{LO}}e^{i\phi_{\text{LO}}}$ is directly proportional to the cavity amplitude $|\tilde{a}_{\text{cavity}}|$ and phase fluctuations $\delta\phi_{\text{cavity}}(t)$ resulting from the stochastic resonant frequency. An electronic spectrum analyzer is used to measure the power spectral density S_{vv} of this homodyne voltage signal.

C. Phase Noise Calibration

The resonant frequency noise spectral density $S_{\omega\omega}$ can then be determined from S_{vv} using the absolute calibration technique discussed in Refs. [S17, S18]. For example, consider a Mach-Zehnder interferometer with input power P_{in} and splitting ratio η_h , which creates the in-phase local oscillator and cavity input signals

$$\tilde{a}_{\rm LO} = \sqrt{\eta_H P_{\rm in}} \qquad \qquad \tilde{a}_{\rm in} = \sqrt{(1 - \eta_H) P_{\rm in}}. \tag{S75}$$

Assuming resonant drive ($\Delta = \omega_L - \omega_0 = 0$) for a cavity with input/output power coupling rate Γ_c , total loss rate Γ_l , and a perturbative resonant frequency noise $\delta\omega(t)$, the output cavity signal is then

$$\tilde{a}_{\rm out} = \sqrt{(1 - \eta_H) P_{\rm in}} \frac{\Gamma_c}{\Gamma_l + i\delta\omega(t)},\tag{S76}$$

yielding a homodyne detection voltage

$$v_h(t) \approx 2G_c |\tilde{a}_{\rm LO}| |\tilde{a}_{\rm out}| \delta \phi_{\rm cavity}(t)$$

$$v_h(t) \approx 2G_c \sqrt{\eta_H (1 - \eta_H)} P_{\rm in} \frac{\Gamma_c}{\Gamma_l^2} \delta \omega(t)$$
(S77)

for a detector conversion gain G_c . The final frequency noise spectral density

$$S_{vv}^{\delta\omega} \approx \underbrace{4G_c^2 \eta_H (1 - \eta_H) \left(\frac{\Gamma_c}{\Gamma_l^2}\right)^2 P_{\rm in}^2}_{K_{\rm expt}} S_{\omega\omega} = K_{\rm expt} S_{\omega\omega}$$
(S78)

is therefore a function of various experimental constants and cavity coupling parameters.

However, the value of K_{expt} can be exactly determined by injecting a known phase noise $\delta\phi(t) = \phi_m(V_p)\cos(\omega_m t)$ into the interferometer with an electro-optic modulator driven with an electrical tone with frequency ω_m and peak voltage V_p . Under the same experimental conditions, the local oscillator and cavity input signals are

$$\tilde{a}_{\rm LO} = \sqrt{\eta_H P_{\rm in}} e^{i\phi_m(V_p)\cos(\omega_m t)} \qquad \tilde{a}_{\rm in} = \sqrt{(1-\eta_H)P_{\rm in}} e^{i\phi_m(V_p)\cos(\omega_m t)}.$$
(S79)

With a small enough modulation depth $\phi_m(V_p) = \pi V_p / V_{\pi}$ (and therefore a small enough drive voltage V_p for a given half-wave voltage V_{π}), the local oscillator can be approximated to first order as

$$\tilde{a}_{\rm LO} \approx \sqrt{\eta_H P_{\rm in}} \left(1 + i \phi_m(V_p) \cos(\omega_m t) \right).$$
(S80)

Similarly, assuming $\omega_m \ll \Gamma_l$ (as is the case in our experiment), the cavity response yields the output signal

$$\tilde{a}_{\text{out}} = \sqrt{(1 - \eta_H)P_{\text{in}}} \left[\frac{\Gamma_c}{\Gamma_l + i\Delta} + i\frac{\phi_m(V_p)}{2} \left(\frac{\Gamma_c}{\Gamma_l + i(\Delta + \omega_m)} e^{i\omega_m t} + \frac{\Gamma_c}{\Gamma_l + i(\Delta - \omega_m)} e^{-i\omega_m t} \right) \right]$$
$$\tilde{a}_{\text{out}} \approx \sqrt{(1 - \eta_H)P_{\text{in}}} \frac{\Gamma_c}{\Gamma_l} \left[1 + i\phi_m(V_p) \left(\cos(\omega_m t) + \frac{\omega_m}{\Gamma_l} \sin(\omega_m t) \right) \right]. \tag{S81}$$

The homodyne signal

$$v_h(t) \approx 2G_c \sqrt{\eta_H(1-\eta_H)} P_{\rm in} \frac{\Gamma_c}{\Gamma_l^2} \omega_m \phi_m(V) \sin(\omega_m t)$$
(S82)

corresponds to a power spectral density

$$S_{vv}^{\delta\phi_m} \approx \underbrace{4G_c^2 \eta_H (1 - \eta_H) \left(\frac{\Gamma_c}{\Gamma_l^2}\right)^2 P_{\rm in}^2}_{K_{\rm expt}} \omega_m^2 S_{\phi\phi} \big|_{\omega = \omega_m},\tag{S83}$$

which, similar to $S_{vv}^{\delta\omega}$, is directly proportional to K_{expt} . K_{expt} can therefore be eliminated to yield an absolute calibration for the resonant frequency noise spectral density:

$$S_{\omega\omega} \approx \frac{S_{vv}^{\delta\omega}}{K_{\text{expt}}} \approx \frac{\omega_m^2 S_{\phi\phi} \big|_{\omega=\omega_m}}{S_{vv}^{\delta\phi_m} \big|_{\omega=\omega_m}} S_{vv}^{\delta\omega}.$$
(S84)

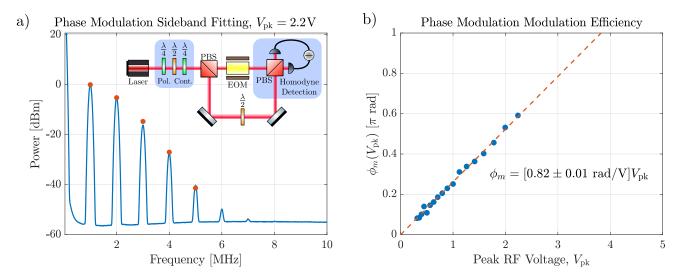


FIG. S4. Measurement of phase modulator modulation depth $\phi_m(V_p)$ at $\lambda = 1550$ nm. A balanced homodyne measurement is performed on the output of a Mach-Zehnder interferometer with the electro-optic modulator (EOM) in one arm, yielding spectra similar to that of (a). The sideband amplitudes are fitted to find the modulation depth at each peak drive voltage V_p , and a linear fit is applied to find the modulation efficiency. The measured value $\phi_m/V_p = 0.82 \pm 0.01$ rad/V corresponds to a half-wave voltage $V_{\pi} = 3.83$ V.

This result can be simplified by evaluating the phase spectral density

$$S_{\phi\phi}(\omega) = \int_{-\infty}^{\infty} \phi_m^2(V_p) \langle \cos(\omega_m t) \cos(\omega_m (t+\tau)) \rangle e^{-i\omega\tau} d\tau = \frac{\phi_m^2(V_p)}{2} \left[\frac{1}{2} \delta(\omega - \omega_m) \frac{1}{2} \delta(\omega + \omega_m) \right].$$
(S85)

The spectrum analyzer convolves the δ -function with the input filter function $F(\omega)$, which is normalized such that $F(0) = \frac{1}{\text{ENBW}}$ [S18], where the effective noise bandwidth ENBW = η_{F} RBW for a resolution bandwidth RBW and a filter shape-dependent $\eta_{\text{F}} \approx 1$. Therefore, the measured noise spectral density evaluated at the modulation frequency ω_m becomes

$$S_{\phi\phi}(\omega = \omega_m) = \frac{\phi_m^2(V_p)}{4} F(\omega) * \delta(\omega - \omega_m) = \frac{\phi_m^2(V_p)}{4 \cdot \text{ENBW}}.$$
(S86)

Using this result, the calibration term in Eqn. S84 can be simplified to a final form

$$S_{\omega\omega}(\omega) = \frac{\omega_m^2 \phi_m^2(V_p)}{4\eta_F \cdot \text{RBW}} \frac{S_{vv}^{\delta\omega}(\omega)}{S_{vv}^{\delta\phi_m}(\omega_m)}$$
(S87)

that agrees with Eqn. 20 of Ref. [S18].

1. Electo-optic Phase Modulator Calibration

Eqn. S87 demonstrates that the calibrated frequency noise can be readily obtained by comparing the recorded RF power spectral density $S_{vv}^{\delta\omega}(\omega)$ to the calibration PSD $S_{vv}^{\delta\phi_m}(\omega_m)$ (which corresponds to a known phase spectral density) for a given calibration frequency $\omega_m/2\pi$ and spectrum analyzer RBW. The ENBW correction factor η_F is a function of various spectrum analyzer settings (see Ref. [S19] for example), and is therefore measured by comparing the noise marker amplitude (dBm/ $\sqrt{\text{Hz}}$) to the measured PSD divided by the RBW. This technique yields $\eta_F \approx 1.057$, which is approximately equal to the value given in Ref. [S19] assuming typical spectrum analyzer settings.

The only remaining unknown parameter required for calibration is the peak-voltage-dependent modulation depth $\phi_m(V_p)$ of the phase modulator, which can be determined with a sideband fitting technique as shown in Fig. S4. An electro-optic phase modulator (EOM) is embedded in one arm of an unbalanced Mach-Zehnder interferometer, yielding a homodyne signal

$$v_h \propto \sum_n J_n(\phi_m) \cos(n\omega_m t)$$
 (S88)

for a modulation frequency ω_m . The power spectrum observed on the spectrum analyzer therefore consists of a periodic sequence of δ -like functions (spectrum analyzer filter functions $F(\omega - n\omega_m)$, to be explicit) at frequencies $\omega_n = n\omega_m$ with powers proportional to $J_n^2(\phi_m)$. Fitting the sideband powers (relative to the n = 1 sideband, as the n = 0 peak is inaccessible on the AC-coupled spectrum analyzer) via a least-squares regression yields $\phi_m(V_p)$ for any peak drive voltage V_p . Fig. S4(a) illustrates the result for $\lambda = 1550$ nm and $V_p = 2.24$ V, where the Bessel functions evaluated at $\phi_m \approx 0.6$ rad (red points) are well fitted to the measured (blue curve) peak amplitudes. After repeating the experiment for multiple values of V_p , a linear fit (Fig. S4(b)) gives the modulation efficiency

$$\left| \eta_{\text{mod}} = \frac{\phi_m}{V_p} \right|_{\lambda_0 = \lambda_{\text{cal}}} = \frac{\lambda_{\text{cal}}}{\lambda_0} \frac{\phi_m}{V_p} \right|_{\lambda_0 = \lambda_{\text{cal}}} = 0.82 \pm 0.01 \text{ rad/V}$$
(S89)

corresponding to a half-wave voltage $V_{\pi} = 3.75$ V (roughly in line with the manufacturer quoted value of 3.17 V) at the calibration wavelength.

Note that the DC phase of the fiber interferometer in this experiment was unstable, and was therefore allowed to drift while the measurement was averaged on a timescale much longer than the drift – a standard technique [S20] which only affects the total power of the homodyne signal, not the quantity of interest (relative magnitude of the sidebands).

2. Balanced Homodyne Detector Characterization

Using the measured EOM modulation efficiency, the calibrated thermo-refractive noise measurements in Fig. 2 of the main text were obtained by measuring the cavity reflection with the stabilized homodyne detector in Fig. S3. We confirmed that the balanced photodetection was shot noise limited (with 10 dB of shot noise clearance) for frequencies greater than ~ 100 kHz and balanced the interferometer arms to well within 1 mm – over an order of magnitude shorter than the expected cavity delay (\sim cm). This was achieved by tuning a retroreflector-based delay line while observing pulse delays from a picosecond fiber laser on both interferometer paths.

D. Additional Measurements for Varying Probe Powers

In the main text, we note that the measured frequency noise spectra are independent of the cavity probe power for sufficiently low input powers. This claim is supported by Fig. S5, which plots the calibrated, background-corrected L4/3 cavity frequency noise spectra for various normalized input powers \tilde{P}_{in} . The inset depicts the nearly constant integrated noise as a function of \tilde{P}_{in} . The range of plotted input powers (spanning about an order of magnitude) is limited by the setup and characteristics of the PhC cavities: the homodyne measurement fails to properly lock if the input power is too low (further frustrated by the signal loss when coupling the non-Gaussian PhC emission into single mode fiber), whereas too high of an input power excites nonlinear intracavity effects, such as two-photon absorption (further details in Section II G).

E. Summary of Experimental Parameters

Table I summarizes the various experimental parameters used to generate the data and fit parameters shown in the main text. Note that, as described in the caption of Fig. 2 of the main text, the expected thermal diffusivity is based on thermal conductivity measurements in thin silicon films [S14] and the hole lattice porosity ϕ [S21]. The porosity $\phi = 3\pi r^2/(3\sqrt{3}a^2/2 - 3\pi r^2)$ — calculated as the ratio of hole area $3\pi r^2$ (assuming a hole radius r) to material area within a hexagonal unit cell of a lattice with lattice constant a — reduces the thin film diffusivity to $D_T = D(1-\phi)/(1+\phi)$ [S21]. This "restricted" diffusivity is used to calculate the expected decay rates in Fig. 2 of the main text.

F. Finite Element Fluctuation-Dissipation Simulations

As schematically outlined in Fig. S6, the approximate spectrum of thermo-refractive noise in microcavities can be computed using Levin's modified form of the Fluctuation-Dissipation theorem [S23, S24]. In this formulation, fluctuations of a readout variable $y = \int q(\vec{r}) x(\vec{r}) d^3 \vec{r}$ — the spatial average of the generalized coordinate $x(\vec{r})$ weighted

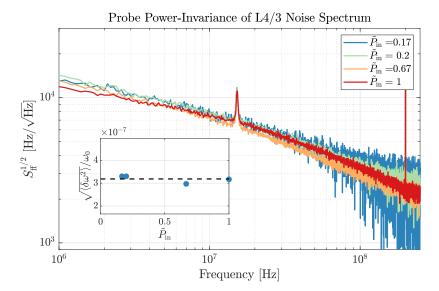


FIG. S5. L4/3 resonant frequency noise $S_{\rm ff}$ measurements as a function of the input power $\tilde{P}_{\rm in}$. $\tilde{P}_{\rm in}$ is normalized to the maximum input probe power for the dataset. The rms fractional frequency fluctuation $\sqrt{\langle \delta \omega^2 \rangle}/\omega_0$ is computed from the integrated noise over the plotted measurement bandwidth and plotted in the inset as a function of $\tilde{P}_{\rm in}$. No significant power scaling or deviation from the mean value (black dashed line) is observed, indicating that noise contributions from nonlinear effects can be neglected.

Parameter	\mathbf{Symbol}	Value	Source
Temperature	T	295.68 K	Measured
Si Refractive Index	$n_{ m Si}$	3.48	[S22]
Si Thermo-optic Coefficient	$\alpha_{\mathrm{TO}}^{\mathrm{Si}}$	$1.8 \times 10^{-4} \ \mathrm{K}^{-1}$	[S22]
Si Specific Heat	c_V^{Si}	$1.64 \text{ J/cm}^3 \cdot \text{K}$	[S14]
Si Thermal Conductivity	$\kappa_{\rm Si}$	$70 \text{ W/m} \cdot \text{K}$	[S14]
Si Thermal Diffusivity (thin film)	D^{Si}	$0.43 \text{ cm}^2/\text{s}$	κ/c_V
Lattice Porosity	ϕ	$\{0.29, 0.26\}$	Calculated
Patterned Thermal Diffusivity	$D_{\mathrm{T}}^{\mathrm{Si}}$	$\{0.23, 0.25\} \text{ cm}^2/\text{s}$	$D^{\rm Si}(1-\phi)/(1+\phi)$ [S21]
Resonant Wavelength	λ_0	{1559.3, 1551.5} nm	Measured
Quality Factor	Q_l	$\{168,000,163,000\}$	Measured
Phase Modulator Efficiency	$\eta_{ m mod}$	0.821 rad/V	Measured (1550 nm)
ESA Noise Correction Factor	η_F	1.057	Measured
Mode Confinement Factor	$\gamma_{\rm Si}$	$\{0.96, 0.95\}$	Simulated
Mode Volume	$\tilde{V}_{\rm eff}$	$\{0.95, 0.32\}$	Simulated
Thermal Mode Volume	\tilde{V}_T	$\{3.92, 1.51\}$	Simulated (Eqn. S16)

TABLE I. Parameters used for calibrating the noise spectrum and computing or fitting Γ_T and V_T . Independent values n for L3 and L4/3 microcavities are listed as $\{n_{L3}, n_{L4/3}\}$ for cavity-dependent parameters. The mode confinement factor $\gamma_{Si} \sim 1$ confirms the validity of Eqn. S87, which assumes complete confinement of the mode in silicon.

by $q(\vec{r})$ — are calculated by driving the momentum conjugate to x with a harmonic force $F(\vec{r},t) = F_0 q(\vec{r}) \cos(\omega t)$. The resulting noise spectrum at the equilibrium temperature T,

$$S_{yy}(\omega) = \frac{2k_B T}{\pi \omega^2 F_0^2} W_{\text{diss}},\tag{S90}$$

Finite-Element Fluctuation-Dissipation Theorem Simulations

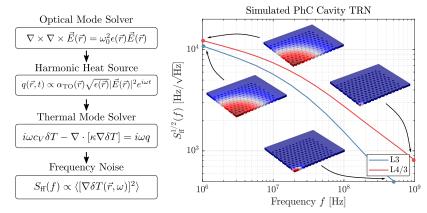


FIG. S6. Fluctuation-Dissipation simulations for thermo-refractive noise. A harmonic heat source with the same shape as the optical mode generates a harmonic temperature profile from which the dissipated power — and therefore the fluctuation — are calculated. The resulting noise spectra for the L3 and L4/3 cavities is shown (right) along with a few characteristic temperature profiles (where the color scale varies from blue to red for the range $\delta T \in [0, \delta T_{max}]$). At low frequencies, the thermal diffusion length is much longer than the characteristic dimensions of the optical mode. The resulting temperature profiles and noise spectral densities of either cavity converge. The opposite is true at high frequencies: the temperature profiles closely follow the shapes of the distinct optical modes, and $S_{\rm ff}$ varies significantly between the two cavities.

is then computed from the time-averaged dissipated power W_{diss} . In the case of thermo-refractive noise in a homogeneous medium (a suitable assumption for highly confined "dielectric mode" PhC cavities),

$$y = |\delta\omega| = \int \underbrace{\frac{\omega_0}{n} \alpha_{\rm TO} \frac{|\vec{E}(\vec{r})|^2}{\int |\vec{E}(\vec{r'})|^2 \mathrm{d}^3 \vec{r'}}_{q(\vec{r})}}_{\delta T(\vec{r}) \mathrm{d}^3 \vec{r}}$$
(S91)

The power dissipated from irreversible heat flow following the harmonic injection of the volumetric entropy density $F(\vec{r},t)$ (conjugate to δT) is [S24]

$$W_{\rm diss} = \int \frac{\kappa}{T} \langle [\nabla \delta T(\vec{r}, t)]^2 \rangle {\rm d}^3 \vec{r}, \qquad (S92)$$

where κ is the material thermal conductivity and $\delta T(\vec{r}, t)$ is the resulting harmonic temperature profile.

Fig. S6 summarizes the computational steps to implement this procedure and the resulting noise spectra. We first use a finite element eigensolver to compute the optical mode $|\vec{E}(\vec{r})|$. A harmonic heat source with magnitude $Q = TF(\vec{r}, t)$ is used as the source in a frequency-domain heat equation solver, which yields the harmonic temperature profile $\delta T(\vec{r})$ from which the noise spectral density $S_{\omega\omega}$ is computed at the drive frequency. Iteratively running the heat equation solver at each frequency of interest then yields the desired noise spectrum $S_{\omega\omega}(\omega)$. The material properties used in the simulations match those assumed for our experiment (and corresponding fits), and are therefore listed in Table I.

G. Comparison of Other Noise Sources

Other stochastic processes can also produce resonant frequency noise. Here we consider two such sources: 1) multiphoton absorption leading to photothermal shot noise from free carrier recombination, and 2) self phase modulation. Both noise sources evaluated at their respective nonlinear thresholds — as an estimate of the "worst case" maximum noise levels — are found to be more than a factor of two weaker than TRN. Since the cavity is measured well within the linear regime, we find that TRN dominates both other contributions combined, thus further confirming our experimental measurements.

1. Multi-Photon Absorption

Multi-photon absorption (MPA) within the resonator leads to a free carrier population that stochastically recombines, producing random local heating analogous to fundamental thermo-refractive noise. Considering this similarity, we can analyze the MPA photothermal shot noise by redefining the statistics of the mode averaged temperature driving force $\bar{F}_T(t)$ in Eqn. S9. The mean rate of intra-cavity k-photon absorption is [S25]

$$\langle r_{k\rm PA} \rangle = \frac{\beta_k}{k\hbar\omega_0} I^k_{\rm pk} V_{k\rm PA},\tag{S93}$$

where $I_{\rm pk} = c|\tilde{a}|^2/2nV_{\rm eff}$ is the peak intensity of the stored energy $|\tilde{a}|^2$, β_k is the k-photon absorption coefficient, c is the speed of light, and $V_{k\rm PA} = \int_{\rm dielectric} |\vec{E}(\vec{r})|^{2k} {\rm d}^3 r/{\rm max} \{|\vec{E}(\vec{r})|^{2k}\}$. Note that we assume that the heating produced by the photoexcited free carriers is local (i.e. no carrier diffusion). The variance of $\bar{F}_T(t)$ is then determined from the temperature change expected from the variance of MPA events within an infinitesimally small time (a Poisson process), yielding the autocorrelation

$$\langle \bar{F}_{T,k}^*(t)\bar{F}_{T,k}(t')\rangle = \frac{k\hbar\omega_0}{c_V^2}\beta_k I_{\rm pk}^k V_{k\rm PA}\delta(t-t').$$
(S94)

Following the method of Section IA, we arrive at the spectral density

$$S_{\omega\omega}^{k\mathrm{PA}}(\omega) = \left(\frac{\omega_0}{n}\alpha_{\mathrm{TO}}\right)^2 \frac{k\hbar\omega_0}{c_V^2} \beta_k I_{\mathrm{pk}}^k V_{k\mathrm{PA}} \frac{1}{\Gamma_T^2 + \omega^2},\tag{S95}$$

which can be evaluated for any intra-cavity stored energy. Here, we consider $I_{\rm pk}$ at the nonlinear threshold, i.e. the peak intensity for a linewidth resonance shift $|\langle \Delta \omega \rangle|/2\Gamma_l = \alpha_{\rm TO} \langle \Delta T_{k\rm PA} \rangle Q_l/n = 1$. The threshold intensity can therefore be derived from the steady state value of Eqns. S9, which lends the average temperature change

$$\langle \Delta T_{k\text{PA}} \rangle = \frac{k\hbar\omega_0 \langle r_{k\text{PA}} \rangle}{c_V V_{k\text{PA}} \Gamma_T} = \frac{\beta_k I_{\text{pk}}^k}{c_V \Gamma_T}.$$
(S96)

Substituting this result into the spectral density equation assuming two-photon absorption as the dominant process (true for our silicon cavities driven at ~ 1550 nm), we can simplify to the final result

$$S_{\omega\omega}^{2\text{PA,threshold}}(\omega) = \left(\frac{\omega_0^2}{n}\alpha_{\text{TO}}\right) \frac{\hbar\omega_0}{c_V Q_l V_{\text{eff}}^{(2)}} \frac{2\Gamma_T}{\Gamma_T^2 + \omega^2}$$
(S97)

for the nonlinear mode volume $V_{\text{eff}}^{(2)} = V_{2\text{PA}}$ (c.f. Eqn. S25). This result is plotted in Fig. S7 assuming the experimental parameters of our devices listed in Table I. Comparing with Eqn. S32, we find $S_{\omega\omega}^{2\text{PA},\text{threshold}}/S_{\omega\omega}^{\text{TRN}} = (nV_T/\alpha_{\text{TO}}T)(\hbar\omega_0 V_{\text{eff}}^{(2)}/k_BT)$, which accounts for the factor of ~2 weaker maximum photothermal shot noise in our devices as shown in Fig. S7. We operate with an input power much lower than the nonlinear threshold power (such that $\langle \Delta\omega_{2\text{PA}} \rangle \ll \Gamma_l$), so the experimental photothermal shot noise is substantially weaker than the maximum value calculated here.

2. Kerr Self Phase Modulation

When confined in a $\chi^{(3)}$ nonlinear material, Poissonian fluctuations of the mean intra-cavity photon number impart self phase modulational (SPM) noise on the resonant frequency. From first-order perturbation theory, the Kerr index change $\delta n(\vec{r}) = 3\chi^{(3)}\epsilon(\vec{r})|\vec{E}(\vec{r})|^2/8\epsilon_0 n^3$ results in a resonant frequency shift

$$\left(\frac{\delta\omega(t)}{\omega_0}\right)_{\text{Kerr}} = -\frac{3\chi^{(3)}}{4\epsilon_0 n^4 V_{\text{Kerr}}} \delta|\tilde{a}(t)|^2 \tag{S98}$$

where ϵ_0 is the free space permittivity, $|\tilde{a}(t)|^2$ is the stored energy, and the Kerr mode volume V_{Kerr} is equal to the thermal mode volume V_T [S26]. When driven with a classical source, the intra-cavity energy autocorrelation

$$\langle |\tilde{a}(t)|^2 |\tilde{a}(t')|^2 \rangle = \left(\frac{2\Gamma_c}{\Gamma_l^2 + \omega^2}\right)^2 \hbar \omega_0 \langle |\tilde{s}_{\rm in}|^2 \rangle \delta(t - t') \tag{S99}$$

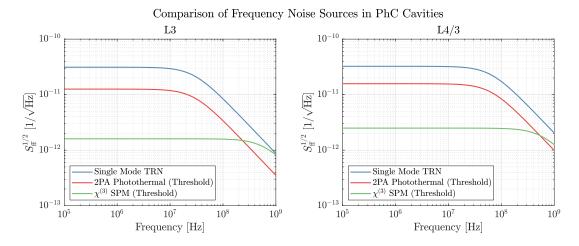


FIG. S7. Approximate spectrum of microcavity noise sources for the experimental parameters in Table I. Note that $S_{\rm ff}^{1/2}$ is plotted as a fractional stability (units $1/\sqrt{\rm Hz}$ to aid comparison with cavity stabilization literature. Noise from two-photon absorption (2PA) and self phase modulation (SPM) at their respective nonlinear threshold powers — which approximates the maximum noise level — is still smaller than TRN.

can derived from temporal coupled mode theory assuming a constant pump power $\langle |\tilde{s}_{in}|^2 \rangle$ coupled at rate Γ_c to a cavity with composite amplitude decay rate Γ_l . The corresponding resonant frequency autocorrelation can then be used to compute the noise spectral density

$$S_{\omega\omega}^{\rm SPM}(\omega) = \left(\frac{3\chi^{(3)}}{4\epsilon_0 n^4 V_T}\right)^2 \left(\frac{2\Gamma_c}{\Gamma_l^2 + \omega^2}\right)^2 \hbar \omega_0^3 \langle |\tilde{s}_{\rm in}|^2 \rangle. \tag{S100}$$

Similar to the multi-photon absorption case, we evaluate this result at the nonlinear threshold $\langle \Delta \omega_{\text{Kerr}} \rangle / 2\Gamma_l = 1$ for a conservative estimate of the associated noise. The final result, considering $\Gamma_c \approx \Gamma_l$ due to the efficient vertical coupling afforded by a superimposed grating (Section II A), is

$$S_{\omega\omega}^{\text{SPM,threshold}}(\omega) = \left(\frac{3\chi^{(3)}}{4\epsilon_0 n^4 V_T Q_l}\right) \left(\frac{2\Gamma_l}{\Gamma_l^2 + \omega^2}\right) \hbar \omega_0^3.$$
(S101)

Even at the threshold power, Fig. S7 shows that the SPM noise is over an order of magnitude weaker than TRN.

III. COMPARISON OF TRN IN VARIOUS MATERIALS

Surprisingly, the $Q_{\text{eff}}^{\text{max}}/V_{\text{eff}}$ limits shown in Fig. 3 of the main text for several common materials lie within an order of magnitude. As shown in Table II, this observed invariance can be attributed to a inverse relationship between the thermo-optic coefficient and thermal diffusivity in common materials. Yet this relationship is not fundamental: aluminum nitride, for example, is shown to outperform all other plotted materials by over an order of magnitude due to its simultaneously large thermal conductivity and small thermo-optic coefficient. This realization demonstrates the importance of material choice when designing state-of-the-art high- Q/V_{eff} resonators.

IV. EFFECTS OF TRN ON ALL-OPTICAL QUBITS

A. Derivation of Qubit Coupling Strengths

This section derives the figures of merit for qubit operation in nonlinear optical cavities. For more information, see Refs. [S27, S28]. The procedure is to first derive the classical equations of motion for fields in nonlinear oscillators and then to quantize them, deriving the Hamiltonian and the single-photon coupling strength. In classical cavity electrodynamics, a cavity field can be expressed as a sum of resonant modes:

$$E(\vec{x},t) = \sum_{\omega} C_{\omega} (A_{\omega}(t) E_{\omega}(\vec{x}) e^{-i\omega t} + \text{c.c.}), \quad C_{\omega} = \sqrt{\hbar \omega / 2\epsilon_0}$$
(S102)

Material	$\mathbf{Index}\ n$	TO coeff. $\alpha_{\rm TO} [{\rm K}^{-1}]$	$\begin{array}{c} \mathbf{Density} \\ \rho \; [\mathrm{g/cm^3}] \end{array}$	$\begin{array}{c} \textbf{Heat capacity} \\ c_V ~ [J/g \cdot K] \end{array}$	Thermal diffusivity $D_T \ [\mathrm{cm}^2/\mathrm{s}]$
Si	3.48	1.8×10^{-4}	2.32	0.7	0.8
GaAs	3.38	$2.35 imes 10^{-4}$	5.32	0.35	0.31
InP	3.16	2×10^{-4}	4.81	0.31	0.37
$\mathbf{Si}_3\mathbf{N}_4$	1.99	$2.5 imes 10^{-5}$	4.65	0.7	0.02
$LiNbO_3$	2.21	3.2×10^{-5}	5.32	0.63	7×10^{-3}
AlN	2.19	3×10^{-5}	3.23	0.6	1.47

TABLE II. Material properties used to calculate the thermal noise limits in Fig. 3 of the main text. Aluminum nitride is the only material listed with a favorable thermo-optic coefficient *and* thermal diffusivity.

The modes E_{ω} satisfy the Helmholtz equation $\nabla \times (\nabla \times E_{\omega}) = (n^2 \omega^2 / c^2) E_{\omega}$. This is a generalized eigenvalue equation and the resulting solutions can be orthogonalized: $\int n^2 E_{\omega'}^* E_{\omega} d^3 \vec{r} = c^2 \int B_{\omega'}^* B_{\omega} d^3 \vec{r} = \delta_{\omega'\omega}$. With this normalization, we find that the electromagnetic energy density in the cavity is $U = \sum_{\omega} \hbar \omega |A_{\omega}|^2$. Therefore, A_{ω} is the normalized field operator, where $|A_{\omega}|^2$ gives the number of photons in the mode E_{ω} .

Nonlinear interactions can be treated as perturbations because the nonlinearity is weak on the order of a single optical cycle. The Helmholtz equation acquires a nonlinear polarization $P = \epsilon_0(\chi^{(2)} : E^2 + \chi^{(3)} : E^3 + ...)$, which can be integrated to give perturbations to the equations of motion for A_{ω} [S29]:

$$\nabla \times (\nabla \times E) + \frac{n^2}{c^2} \frac{\partial^2 E}{\partial t^2} = -\frac{1}{c^2} \frac{\partial^2 (P/\epsilon_0)}{\partial t^2} \quad \Rightarrow \quad \frac{\mathrm{d}A_\omega}{\mathrm{d}t} = \frac{i\omega}{2C_\omega} \int E_\omega(\vec{x})^* \Big[\frac{P(\vec{x},t)}{\epsilon_0}\Big]_\omega e^{i\omega t} \mathrm{d}^3 \vec{r} \tag{S103}$$

1. Kerr $(\chi^{(3)})$ Interaction

In the $\chi^{(3)}$ case, we have a cavity with a single resonant mode E_{ω} . The polarization term due to the Kerr interaction is $P = \epsilon_0 \chi^{(3)} : (C_{\omega} A_{\omega} E_{\omega} e^{-i\omega t} + \text{c.c.})^3$. This gives rise to the equation of motion $\dot{A}_{\omega} = -i\chi |A_{\omega}|^2 A_{\omega}$, where:

$$\chi = -\frac{3\hbar\omega^2 \chi^{(3)}}{4n^4\epsilon_0} \frac{1}{V_{\text{Kerr}}}, \quad V_{\text{Kerr}} \equiv \frac{\left(\int n^2 |E_{\omega}|^2 d^3 \vec{r}\right)^2}{\int_* n^4 |E_{\omega}|^4 d^3 \vec{r}}$$
(S104)

Quantizing the field to satisfy the commutation relations $[\hat{A}_{\omega}, \hat{A}_{\omega}^{\dagger}] = 1$ this equation of motion can be generated from the Hamiltonian:

$$H_{\text{Kerr}} = \frac{1}{2} \chi \hat{A}^{\dagger}_{\omega} \hat{A}^{\dagger}_{\omega} \hat{A}_{\omega} \hat{A}_{\omega}$$
(S105)

As an open quantum system, the field interacts with a bath through Lindblad dissipation terms, in this case $L = \sqrt{2\Gamma}A_{\omega}$, where $\Gamma = \omega/2Q$. The figure of merit for strong coupling is:

$$\operatorname{FOM}_{\chi^{(3)}} = \frac{\chi}{2\Gamma} = \underbrace{\frac{3\pi\hbar c}{2n\epsilon_0} \frac{\chi^{(3)}}{\lambda^4}}_{K_{\chi}} \frac{Q}{\tilde{V}_{\operatorname{Kerr}}}$$
(S106)

2. Second-order $(\chi^{(2)})$ Interaction

In this case, we have two fields at frequencies $(\omega, 2\omega)$. The polarization term is: $P = \epsilon_0 \chi^{(2)}$: $(C_{\omega}A_{\omega}E_{\omega}e^{-i\omega t} + C_{2\omega}A_{2\omega}E_{2\omega}e^{-2i\omega t} + \text{c.c.})^2$. This gives rise to the following equations:

$$\dot{A}_{2\omega} = -\frac{1}{2}\epsilon A_{\omega}^2, \quad \dot{A}_{\omega} = \epsilon A_{2\omega}A_{\omega}^* \tag{S107}$$

where

$$\epsilon = \frac{\omega \sqrt{\hbar \omega / \epsilon_0}}{n^3 V_{\rm shg}^{1/2}} \chi^{(2)}, \quad V_{\rm shg} = \frac{\left(\int n^2 |E_{2\omega}|^2 {\rm d}^3 \vec{r}\right) \left(\int n^2 |E_{\omega}|^2 {\rm d}^3 \vec{r}\right)^2}{\left|\int_* n^3 E_{2\omega}^* E_{\omega} E_{\omega} {\rm d}^3 \vec{r}\right|^2}$$
(S108)

in the case that \vec{E} and \vec{P} are aligned (otherwise ϵ is reduced by a geometric factor). The integral $\int (\ldots) d^3 \vec{r}$ is taken over all space, while $\int_* (\ldots) d^3 \vec{r}$ is restricted to the nonlinear material.

As before, we can quantize the fields \hat{A}_{ω} , $\hat{A}_{2\omega}$ and derive a Hamiltonian corresponding to Eqs. (S107). As an open quantum system, there will also be Lindblad dissipation terms $\Gamma_1 = \omega/2Q_1$, $\Gamma_2 = 2\omega/2Q_2$:

$$H = -i\epsilon \left(\hat{A}_{2\omega}^{\dagger} \hat{A}_{\omega} \hat{A}_{\omega} - \hat{A}_{\omega}^{\dagger} \hat{A}_{\omega}^{\dagger} \hat{A}_{2\omega} \right), \quad L_1 = \sqrt{2\Gamma_1} A_{\omega}, \quad L_2 = \sqrt{2\Gamma_2} A_{2\omega}$$
(S109)

The figure of merit for strong coupling again is expressed as a ratio of the coupling rate ϵ to the loss rate. Here there are two loss channels, and a common approach is to take the geometric mean of the two (a choice motivated by the limit $Q_2 \ll Q_1$, in which the $\chi^{(2)}$ interaction can be adiabatically eliminated to a $\chi^{(3)}$ one with $\chi/\Gamma \propto \epsilon^2/\Gamma_1\Gamma_2$). Thus we set the figure of merit to be:

$$\text{FOM}_{\chi^{(2)}} = \frac{\epsilon}{2\bar{\Gamma}} = \frac{\epsilon}{2\sqrt{\Gamma_1\Gamma_2}} = \underbrace{\sqrt{\frac{\pi\hbar c}{n^3\epsilon_0}}\frac{\chi^{(2)}}{\lambda^2}}_{K_{\epsilon}} \underbrace{\frac{\sqrt{Q_1Q_2}}{\tilde{V}_{\text{shg}}^{1/2}}}_{K_{\text{shg}}} \tag{S110}$$

In the main text, we assume $Q_1 = Q_2 = Q$ such that $\text{FOM}_{\chi^{(2)}} \propto Q/V_{\text{shg}}^{1/2}$.

B. Parameters

The parameters used to generate Fig. 4 of the main text are included in Table III.

Parameter	\mathbf{Symbol}	Value	Source
$\overline{\chi^{(3)}}$ Nonlinear Index	n_2	$1.2 \times 10^{-13} \text{ cm}^2/\text{W}$	[S30, Sec. 11]
$\chi^{(3)}$ FOM Constant	K_{χ}	8.7×10^{-11}	Calculated (Eqn. S106)
$\chi^{(2)}$ (DC <i>E</i> -Field Induced)	$\chi^{(2)}$	40 pm/V	[S31]
$\chi^{(2)}$ FOM Constant	K_{ϵ}	1.3×10^{-7}	Calculated (Eqn. S110)
Thermo-optic Coefficient	$\alpha_{ m TO}^{ m Si}$	$1.8 \times 10^{-4} \ {\rm K}^{-1}$	[S22]
Thermal Diffusivity	D^{Si}	$0.8 \text{ cm}^2/\text{s}$	[S14]

TABLE III. Silicon material properties assumed to calculate the qubit figures of merit at $\lambda_0 = 2.3 \ \mu m$ and T = 300 K.

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